° ICOM

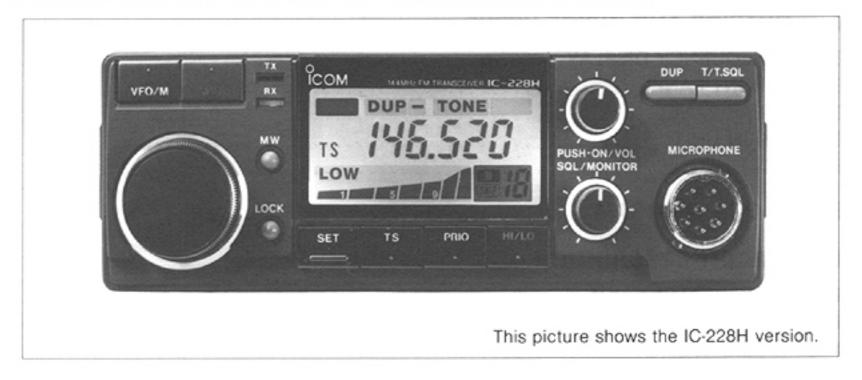
SERVICE MANUAL

144 MHz FM TRANSCEIVER 1C-228A 1C-228E 1C-228H

Icom Inc.

SCOPE OF THE SERVICE MANUAL

This service manual covers all service information related to the theoretical, physical, mechanical and electrical characteristics of the IC-228A/E/H 144MHz FM TRANSCEIVER.



Assistance_

If you require assistance or further information regarding the operation, capability and servicing of the **IC-228A/E/H**, contact your nearest authorized Icom Dealer or Icom Service Center. Addresses are provided on the inside back cover for your convenience.

ORDERING PARTS _

Be sure to include the following five points when ordering replacement parts or requesting equipment information from your dealer or Icom Service Center. This will ensure faster, more efficient service.

- 1. Equipment model and serial number
- 2. Schematic part identifier or service manual page number
- 3. Unit name and printed circuit board number (e.g., MAIN UNIT/B-1680B)
- 4. Component part number and name (e.g., SC-1019 IC)
- 5. Quantity required (e.g., 5pcs.)

REPAIR NOTE ____

- DO NOT open transceiver covers until the transceiver is disconnected from a power source.
- 2. DO NOT connect the transceiver to an external power source of more than 15V.
- 3. DO NOT force any of the variable components. Turn them slowly and smoothly.
- 4. DO NOT short any circuits or electronic parts.
- 5. An insulated tuning tool **MUST BE** used for all adjustments.
- 6. DO NOT keep power ON for a long time when the transceiver is defective.
- 7. DO NOT transmit power into a signal generator or sweep generator.
- Always connect a 20dB or 30dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- Read the instructions of test equipment thoroughly before connecting equipment to the transceiver.

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SECTION 1 SPECIFICATIONS

GENERAL

 Frequency coverage 	:	MODEL	VERSION	RECEIVER	TRANSMITTER
		IC-228A/H	U.S.A.	138.00~174.00 MHz*	140.00~150.00 MHz*
		IC-228A/H	Australia	144.00~148.00 MHz	144.00~148.00 MHz
		IC-228A/H	Asia	138.00~174.00 MHz*	140.00~150.00 MHz*
		IC-228E/H	Europe	144.00~146.00MHz	144.00~146.00 MHz
		IC-228E/H	Italy	140.00~150.00 MHz*	140.00~150.00 MHz*
		•	ons apply to 144.	$00 \sim 148.00 \mathrm{MHz}$ only.	
• Mode	:	F3 (FM)			
 Selectable tuning step (Initial) 	:			.A., Australia, Asia versio	ns)
			Iz (Europe, Ital	y versions)	
Memory channels	:	20 plus a call	channel		
Antenna impedance	:	50 Ω	6 ()		
Power supply requirement	:	13.8V DC±15		ound)	
 Current drain (IC-228H) 	:	Receive 450			
			mA (max. audi	o output)	
			.5A (LOW)		
			.5A (HIGH)		
 Current drain (IC-228A/E) 	:		mA (standby)		
			mA (max. audi	o output)	
			.0A (LOW)		
			.0A (HIGH)		
Usable temperature range	:		℃ (+14°F~+	•	
Frequency stability	:			+14°F∼+140°F)	
 Dimensions 	:			159(D) mm, 5.5(W)×2.0(
				137(D) mm, 5.5(W)×2.0(l	H)×5.4(D) in.
		(Projections no	-		
Weight	:		kg (2.4 lb)		
		IC-228A/E 0.8	15 kg (1.9 lb)		
TRANSMITTER					
Output power		IC-228H 45	W (HIGH), 5W	(1 (1)))	
	·	IC-228A/E 25			
 Modulation system 		Variable reacta			
Max. frequency deviation	:			mounation	
Spurious emissions	:	Less than -60)dB		
Microphone impedance	:	600 Ω			
RECEIVER					
 Receiver system 	:	Double-conver	sion superhete	rodyne	
 Intermediate frequencies 	:	1st 17.2MH	z		
		2nd 455kHz	2		
Sensitivity	:	0.18µV for 120	B SINAD		
Selectivity	:	More than 15	≺Hz/−6dB		
		Less than 301	kHz/—60dB		
 Audio output power 	:	More than 2.4	W at 10% disto	ortion with an 8Ω load	
Audio output impedance		80			

• Audio output impedance : 8Ω

All stated specifications are subject to change without notice or obligation.

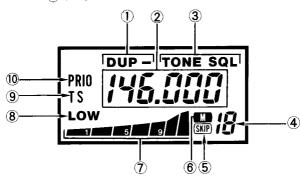
SECTION 2 OUTSIDE AND INSIDE VIEWS

2-1 FREQUENCY DISPLAY

- ① DUPLEX INDICATOR
- 2 FREQUENCY READOUT
- 3 TONE INDICATOR
- MEMORY CHANNEL READOUT
- (5) SKIP CHANNEL INDICATOR

6 MEMORY INDICATOR

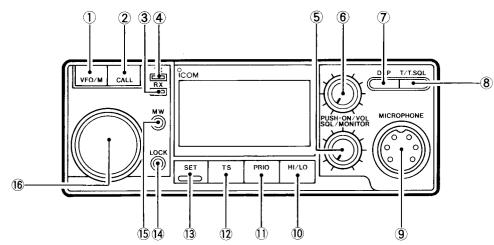
- ⑦ S/RF INDICATOR⑧ LOW POWER INDICATOR
- (9) TUNING STEP INDICATOR
- 10 PRIORITY INDICATOR



2-2 FRONT PANEL

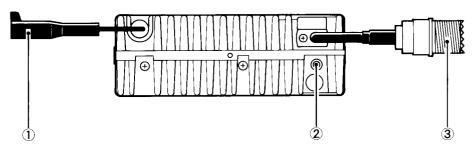
- ① VFO/MEMORY SWITCH [VFO/M]
- ② CALL CHANNEL SWITCH [CALL]
- ③ RECEIVE INDICATOR [RX]
- (4) TRANSMIT INDICATOR [TX]
- (5) SQUELCH CONTROL/MONITOR SWITCH [SQL/MONITOR]
- POWER SWITCH/VOLUME CONTROL [ON/VOL]
- ⑦ DUPLEX SWITCH [DUP]
- (8) TONE SWITCH [T/T. SQL]

- (9) MICROPHONE CONNECTOR
- 1 TRANSMIT POWER SWITCH [HI/LO]
- 1 PRIORITY SWITCH [PRIO]
- 12 TUNING STEP SWITCH [TS]
- (3) SET MODE SWITCH [SET]
- () LOCK SWITCH [LOCK]
- (5) MEMORY WRITE SWITCH [MW]
- 16 MAIN TUNING DIAL

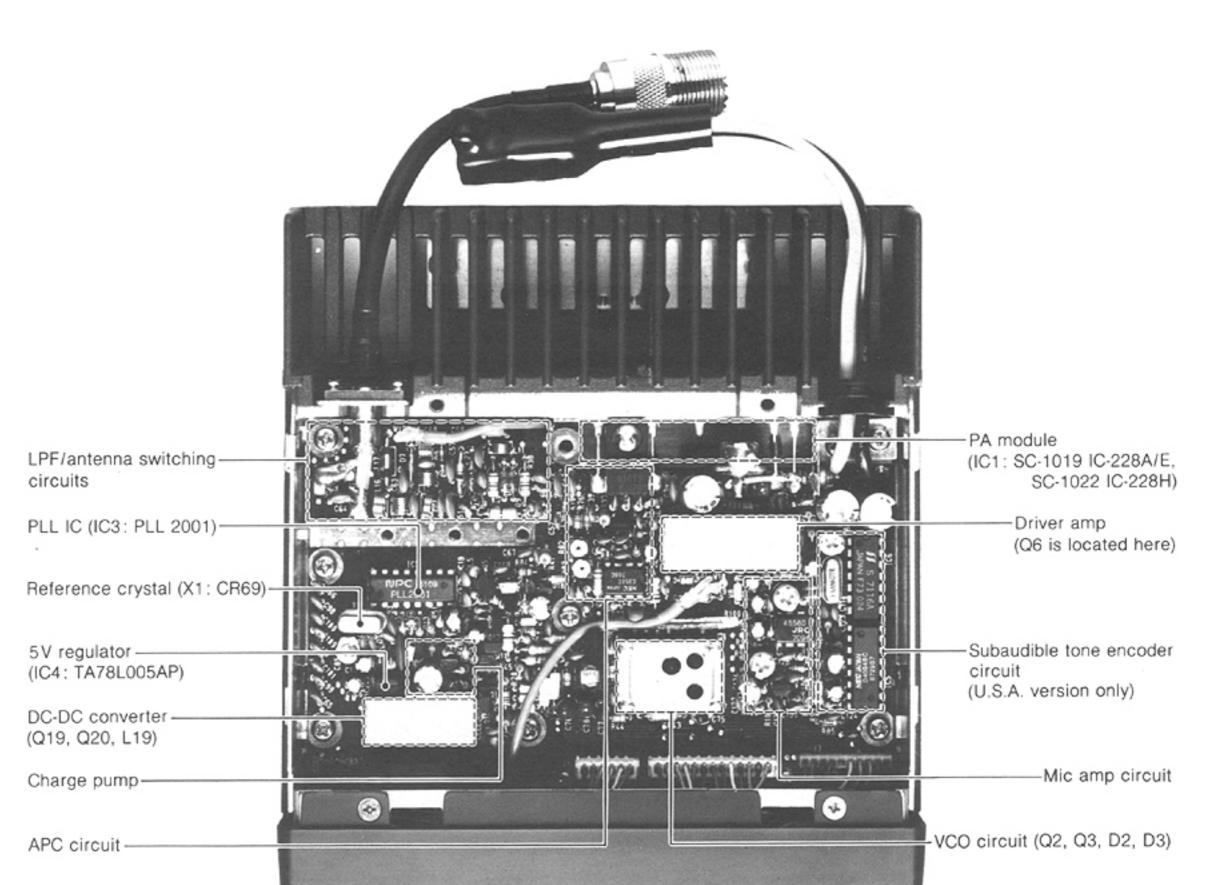


2-3 REAR PANEL

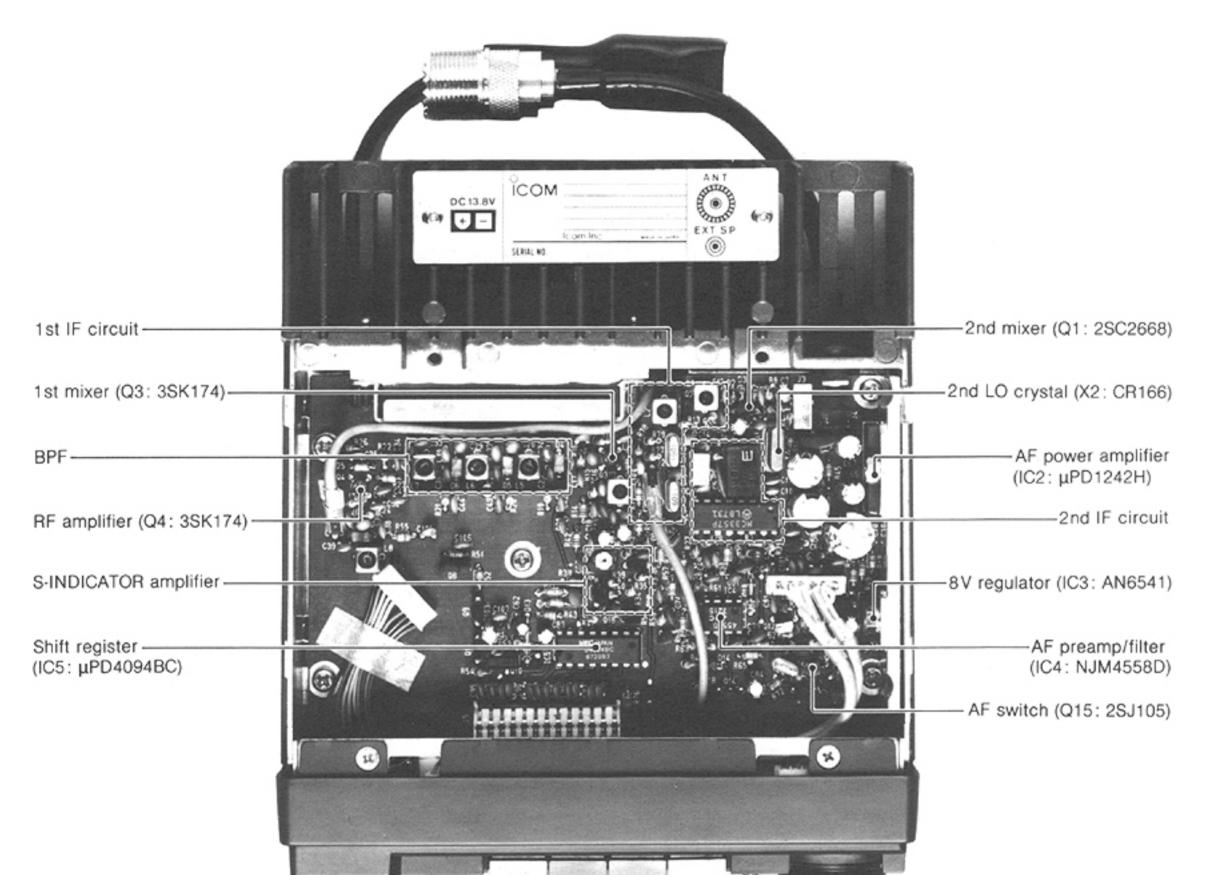
- ① POWER CONNECTOR
- (2) EXTERNAL SPEAKER JACK
- 3 ANTENNA CONNECTOR



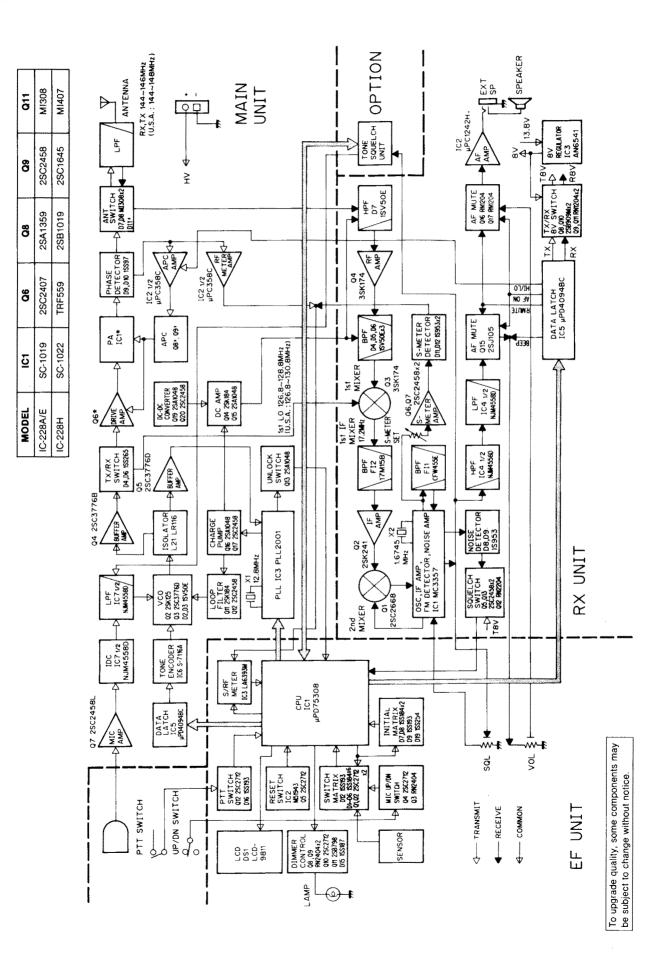
2-4 MAIN UNIT



2-5 RX UNIT







SECTION 3 BLOCK DIAGRAM

SECTION 4 CIRCUIT DESCRIPTION

4-1 RECEIVER CIRCUITS

4-1-1 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

Received signals enter the antenna connector and pass through a low-pass filter (L14 \sim L17, C61 \sim C64), antenna switching circuit (D7, D8, D11) and the other low-pass filter (L12, L13, C57 \sim C59). The signals are applied to the antenna switching circuit (D7, D8, D11) and then to the RX UNIT via coaxial cable P1.

4-1-2 RF CIRCUIT (RX UNIT)

The applied RF signals from the MAIN UNIT are applied to the one-stage bandpass filter (D7, L8, C37), amplified at RF amplifier (Q4), and reapplied to the other bandpass filter (D4 \sim D6, L5 \sim L7, C24, C27, C30) to suppress out-of-band signals.

IF CIRCUIT

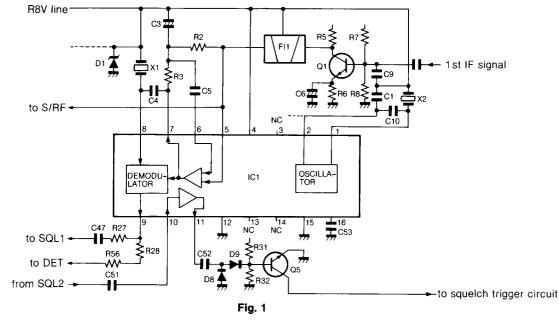
4-1-3 1ST MIXER CIRCUIT (RX UNIT)

1st mixer circuit Q3 converts the RF signal to the 17.2MHz 1st IF signal. RF signals from the bandpass filter are applied to gate 1 of Q3 and the 1st LO signal (PLL output) is applied to gate 2 of Q3. Q3 mixes this RF signal and a 1st LO signal and outputs 17.2MHz.

4-1-4 1ST IF CIRCUIT (RX UNIT)

The 1st IF signal is applied to a pair of mechanical crystal filters (FI2) to suppress out-of-band signals through the matching filter L3 and C16. The signal is then applied to the 2nd IF circuit through amplifier Q2.

D2 and D3 function as the limiter circuit when a strong signal is received.



4-1-5 2ND IF CIRCUITS (RX UNIT)

The 1st IF signal amplified at Q2 is applied to mixer circuit Q1. Q1 mixes the signal with a 16.745 MHz 2nd LO signal to convert the 1st IF signal to a 455 kHz 2nd IF signal. The converted signal is applied to pin 5 of IC1 through ceramic filter FI1.

IC1 contains the 2nd mixer circuit, the 2nd LO circuit and the quadrature detector circuit. X2 generates 16.745MHz for the 2nd LO signal.

Some of the noise components in the detected signal are applied to pin 10 of IC1 through the R2 SQUELCH CONTROL on the front panel. The SQUELCH CONTROL adjusts the noise level.

4-1-6 SQUELCH CIRCUIT (RX UNIT)

Pin 11 of IC1 outputs amplified noise components of frequencies at 20kHz and above. Output signals are rectified by D8 and D9. The rectified voltage triggers the squelch circuit consisting of Q5, Q12 and Q13.

The collector of Q13 outputs the squelch signal and is applied to CPU IC1 in the EF UNIT through the SQL.S line. An output signal of Q12 is applied to analog switch Q15 to control the AF mute circuit.

4-1-7 AF CIRCUIT (MAIN UNIT)

The detected AF signal at pin 9 of IC1 is applied to a twostage active filter consisting of IC4a and IC4b. The filter functions as a de-emphasis circuit of +6dB/octave as well as a high-pass filter for filtering tone signals for the tone squelch.

A filtered signal is applied to AF amplifier IC2 through analog switch Q15, preamplifier Q16 and Q17 and the VOLUME CONTROL on the front panel.

AF amplifier IC2 amplifies the signal to a sufficient level to drive the speaker.

4-2 TRANSMITTER CIRCUITS

4-2-1 MICROPHONE AMPLIFIER (MAIN UNIT)

An AF signal from the microphone is applied to microphone preamplifier Q7 through the MIC line. IC7b functions as an amplifier as well as a limiter for frequency deviation. IC7b also functions as a pre-emphasis circuit with -6 dB/octave characteristics.

4-2-2 MODULATION CIRCUIT (MAIN UNIT)

The signal is filtered by a low-pass filter consisting of IC7a. IC7b has a feedback circuit which functions as a pre-emphasis circuit with +6 db/octave characteristics. The filtered signal is applied to the VCO circuit for FM modulation.

4-2-3 DRIVE AMPLIFIER (MAIN UNIT)

The VCO output signal is buffer-amplified at Q4, and applied to a switching circuit consisting of D4 and D6.

When transmitting, D4 is turned ON and the amplified signal is applied to pre-driver Q6. Q6 amplifies the signal to 200mW and 400mW for IC-228A/E and IC-228H respectively.

4-2-4 POWER AMPLIFIER (MAIN UNIT)

IC1 is a power amplifier and amplifies the signal to approximately 30W and 50W for IC-228A/E and IC228H respectively. The amplified signal at pin 4 of IC1 is applied to a low-pass filter consisting of L14 \sim L16 and C61 \sim C64 to filter out unwanted out-of-band signals.

4-2-5 ANTENNA SWITCHING CIRCUIT (MAIN UNIT)

When transmitting, a diode switching circuit consisting of D7, D8 and D11 is turned ON by a signal of T9V.

Transmit signals are applied to the antenna connector through the low-pass filter.

When receiving, the diode switching circuit is turned OFF and received signals are applied to P1 through a π -type filter consisting of L12, L13 and C57 \sim C59. The filter attenuates unwanted harmonic signals.

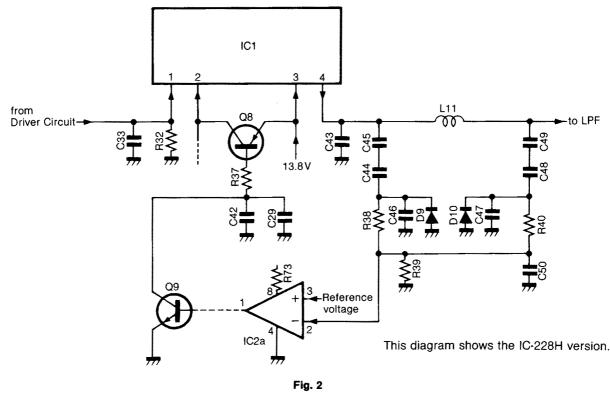
4-2-6 APC CIRCUIT (MAIN UNIT)

L11, C44 \sim C49, D9 and D10 forms a mismatching detector circuit.

When the impedance of the connected antenna is matched with 50Ω , detected voltage at D9 and D10 is at a minimum. However the voltage increases when the antenna impedance is not matched with 50Ω .

The detected voltage is applied to pin 2 of IC2a and a reference voltage is applied to pin 3 of IC2a. Pins 2 and 3 form differential inputs and IC3 functions as a differential amplifier. The relation between the detected voltage level and output voltage level at pin 1 of IC3 is an inverse proportion.

If output power from pin 4 of IC1 is increased, detected voltage by D9 and D10 increases. The voltage is applied to pin 2 of IC2a. Pin 1 of the IC2a output level becomes lower than when the output power is normal. The base voltage of Q9 becomes lower and the collector of Q8 also becomes lower. Therefore, applied voltages to the collector of Q6 and pin 2 of IC1 decrease and the output power is controlled at a constant level.



4 - 2

APC CIRCUIT

4-3 PLL CIRCUITS (MAIN UNIT)

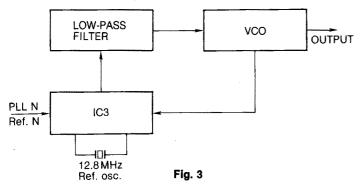
4-3-1 GENERAL

IC3 is one package of the PLL IC chip. The IC functions as a phase detector, reference oscillator, fixed divider and programmable divider.

IC3 accepts 200 MHz signals directly and divides them without a mixer or prescaler. Therefore an important feature in IC3 is that it generates few spurious components.

The VCO output frequency is set by data signals from IC1 on the EF UNIT.

PLL circuit block diagram



4-3-2 VCO CIRCUIT

The VCO circuit forms a Hartley oscillator circuit. Q2 oscillates the desired signal and Q3 functions as a buffer amplifier.

The collector of Q3 outputs signals and the signals are applied to an isolator circuit consisting of L21 and R17 for distributing the signals to both the PLL circuit and driver circuit.

R18, R19 and R20 form a 50Ω attenuator. An attenuator is installed between VCO output and the PLL IC chip to reduce reflected waves due to mismatching.

4-3-3 REFERENCE OSCILLATOR

IC3 has an oscillator circuit for the PLL reference frequency signal in the chip. X1 is a crystal unit for oscillating a signal of 12.8 MHz. The frequency is divided to either 5kHz or 12.5kHz by data signals from CPU IC1 in the EF UNIT.

4-3-4 CHARGE PUMP AND LOOP FILTER CIRCUITS

Phase-detected signals from pins 5 and 12 are converted to DC voltage by a charge pump circuit consisting of Q16 \sim Q18. The signal is then applied to a low-pass filter circuit consisting of R43 \sim R46 and C75 \sim C78.

Filtered DC voltage is applied to D2 and D3 in the VCO circuit for controlling the VCO output frequency and the gate of Q14 for making voltages for receiver tuning.

4-4 OTHER CIRCUITS

4-4-1 REGULATOR CIRCUITS

IC3 on the RX UNIT is a 3-terminal voltage regulator IC chip. +13.8V is applied to pin 1 and pin 3 outputs +9V. The regulated voltage is applied to each unit.

IC4 on the MAIN UNIT is a 3-terminal voltage regulator IC chip. +13.8V is applied to an input terminal and the output terminal outputs +5V.

Q19 and Q20 form a DC-DC voltage converter for applying approximately 30V DC to the receiver RF circuit.

4-4-2 SUBAUDIBLE TONE ENCODER CIRCUIT (IC-228A: U.S.A. AND ASIA VERSIONS)

IC5 is an IC chip for converting input data from serial to parallel form. The data is sent from IC1 on the EF UNIT. IC6 is an IC chip for generating subaudible tone frequency signals from $67 \text{Hz} \sim 250.3 \text{Hz}$. The following table shows the relation between input data and the output frequency of IC6.

OUTPUT FREQUENCY	IC	26 INI	PUT F	N NI	UMBE	R	OUTPUT FREQUENCY	10	6 INI	PUT F	IN NU	JMBE	R	OUTPUT	ю	C6 INF	PUT P	IN N	JMBE	R
[Hz]	8	9	10	11	12	13	[Hz]	8	9	10	11	12	13	[Hz]	8	9	10	11	12	13
67.0	н	L	L	L	L	L	107.2	L	н	н	н	L	L	167.9	н	н	L	н	н	L
71.9	L	н	L	L	L	L	110.9	н	н	н	н	L	L	173.8	L	L	н	н	н	L
74.4	н	н	L	L	L	L	114.8	L	L	L	L	н	L	179.9	н	L	н	н	н	L
77.0	L	L	н	L	L	L	118.8	н	L	L	L	н	L	186.2	L	н	Н	н	н	L
79.7	н	L	н	L	L	L	123.0	L	н	L	L	н	L	192.8	Н	н	н	н	Н	L
82.5	L	н	н	L	L	L	127.3	н	Н	L	L	н	L	203.5	L	F	L	L	L	н
85.4	н	н	н	L	L	L	131.8	L	L	н	L	н	L	210.7	н	L	L	L	L	н
88.5	L	L	L	н	L	L	136.5	Н	L	н	L	н	L	218.1	L	н	L	L	L	н
91.5	Н	L	L	н	L	L	141.3	L	Н	Н	L	н	L	225.7	н	Н	L	L	L	н
94.8	L	н	L	Н	L	L	146.2	Н	Н	н	L	Н	L	233.6	L	L	Н	L	L	н
97.4	H	н	L	н	L	L	151.4	L	L	L	Н	Н	L	241.8	н	L	Н	L	L	н
100.0	L	L	н	н	L	L	156.7	Н	L	L	н	Н	L	250.3	L	н	н	L	L	н
103.5	н	L	н	н	L	L	162.2	L	Н	L	н	н	L							

SUBAUDIBLE TONE ENCODER FREQUENCY TABLE (IC-228A: U.S.A., ASIA VERSIONS)

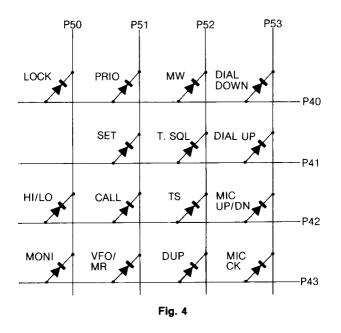
4-5 LOGIC CIRCUITS (EF UNIT)

4-5-1 CPU PORT ALLOCATIONS

PORT NUMBER	PIN NUMBER	DESCRIPTION
RESET	68	When a "HIGH" signal is applied here the CPU is initialized or changes to standby mode.
P00 [INT4]	38	Detects a signal for the standby mode of the CPU. The CPU enters the standby mode when the port reads a trailing edge of the signal.
P01 [SCK]	39	Outputs data signals.
P02 [DATA]	40	Outputs serial data synchronized with the SCK signal.
P03 [SQLS]	41	Detects a squelch signal. When the signal is "HIGH," the squelch opens.
P10~P13 [KIR0~KIR3]	42~45	Input ports for the initial matrix.
P20	46	Not used.
P21 [STBRX]	47	Outputs a strobe signal for serial data to the output expander.
P22 [STBPLV]	48	Outputs a strobe signal for serial data to the PLL IC.
P23	49	Not used.
P30 [UNLKV]	50	Detects a PLL unlock signal. When the signal is "HIGH," the PLL is unlocked. Normally the port is "LOW."
P31	51	Not used.
P32 [TXLED]	52	Outputs a signal for turning the TRANSMIT indicator ON and OFF. The port becomes "LOW" and "HIGH" when transmitting and receiving (squelch opens) respectively.
P33 [SRFO]	53	Outputs a reference voltage for the S/RF indicator.
P40~P43 [KR0~KR3]	29~32	These are input ports for the key matrix.
P50~P53 [KS0~KS3]	34~37	These are output ports for strobe signals for the initial and key matrix.
P60 [SRFI]	60	Inputs a reference voltage for the S/RF indicator.
P61 [PTT]	61	Inputs a signal on the PTT line. The port should be "HIGH" when the PTT switch is pushed.
P62 [TSQL]	62	Input port for an acknowledge signal in the tone squelch unit. The port is "HIGH" when the tone squelch opens.
P63 [OPT]	63	Input port whether the tone squelch is installed or not. The port is "LOW" when the tone squelch is installed.
P70 [STBOP]	64	Outputs a strobe signal for serial data to the tone squelch unit (MN6520).
P71 [STBCT]	65	Outputs a strobe signal for serial data to the subaudible tone IC (S7116).
P72, P73 [DIM01, DIM02]	66, 67	Outputs a signal for controlling intensity of the FUNCTION DISPLAY. Refer to Table 2.

Table 2

4-5-2 KEY MATRIX



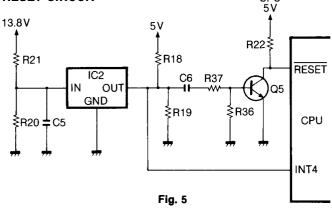
4-5-3 RESET CIRCUIT

The CPU is reset when the RESET port changes from "HIGH" to "LOW" and then becomes "LOW" again. The

CPU

RESET CIRCUIT

RESET TIMING CHART



RESET port remains "HIGH" except when the CPU is reset. The following is a diagram for the reset circuit and timing chart.

13.8V INT4 RESET OV RESET OV POWER ON Fig. 6

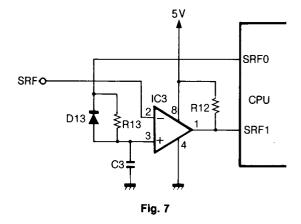
4-5-4 S/RF INDICATOR CIRCUIT

IC3 functions as a comparator. Pin 53 of IC1 outputs "HIGH" as a reference voltage to a detected S/RF signal level.

Relative signal strength indicator

When receiving, Q6 and Q7 on the RX UNIT amplifies a 455kHz 2nd IF signal. D11 and D12 on the RX UNIT rectify the signal to be converted to DC voltage as the S/RF signal. The signal is applied to pin 2 of IC3 on the EF UNIT. Pin 1 of IC3 on the EF UNIT outputs "HIGH" when the voltage at pin 3 becomes the same as or higher than the SRF voltage at pin 2. It takes time to output "HIGH" from pin 1 of IC3 after pin 53 of IC1 on the EF UNIT outputs "HIGH". The time depends on the level of the SRF voltage. The higher the level of SRF voltage the longer time it takes. IC1 measures the time and the FUNCTION DISPLAY indicates the relative signal strength.

S/RF INDICATOR CIRCUIT



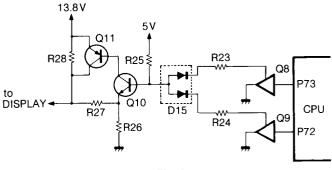
• RF output power selection indicator

IC2b on the MAIN UNIT amplifies RF output power. The gain of IC2b is set very high, so the output voltage at pin 7 of IC2b is saturated even if the input RF level is small. Then the "HIGH" is applied to pin 2 of IC3 on the EF UNIT. Pin 1 of IC3 is "HIGH" when the power module of IC1 on the MAIN UNIT outputs power. IC1 on the EF UNIT detects either HIGH or LOW output power with the key matrix of P42 and P50.

4-5-5 DIMMER CIRCUIT

The FUNCTION DISPLAY changes its brightness at 4 levels using combinations of output level at P72 and P73. By changing levels at P72 and P73, the base voltage and collector current changes. Therefore, the collector voltage is changed and brightness of lamps DS2~DS4 changes.

DIMMER CIRCUIT

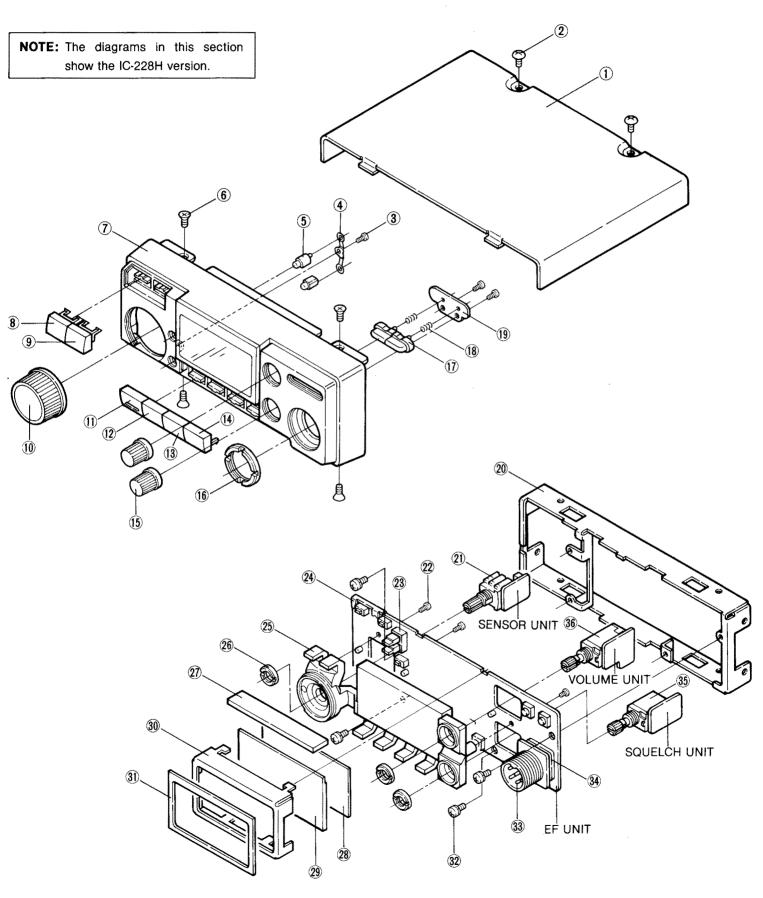


BRIGHTNESS	P72	P73	INDICATION
A	н	н	d-4
Brightness	L	н	d-3
Dark	н	L	d-2
*	L	L	d-1

H: HIGH L: LOW

SECTION 5 DISASSEMBLY AND ASSEMBLY DIAGRAMS

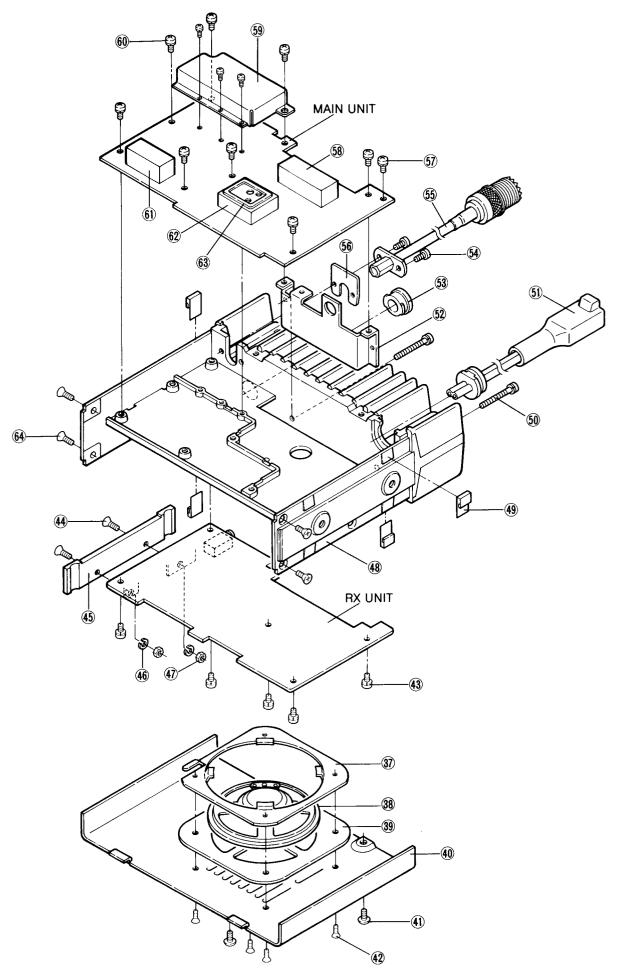
5-1 FRONT PANEL DISASSEMBLY



LABELLED NUMBER	DESCRIPTION	ORDER NUMBER	QTY.
	495 Top Cover (A)-1 (IC-228A/E)	8110002130	1
1	301 Top Cover (A)-1 (IC-228H)	8110002070	1
2	ICOM Screw (B) 4	8810003700	2
3	PH B0 2×5	8810000990	1
4	671 Switch Spring	8930013020	1
5	K-113 Button	8610004330	2
6	FH M2.6×4	8810002100	4
	671 Front Panel (A) (IC-228A)	8210003510	1
\overline{O}	671 Front Panel (A) (IC-228E)	8210003520	1
	671 Front Panel (A) (IC-228H)	8210003360	1
8	K-114 Button (E) (VFO/M)	8610004500	1
9	K-114 Button (F) (CALL)	8610004510	1
10	N-130 Tuning Control Knob	8610004400	1
Û	K-115 Button (A) (SET)	8610004520	1
(2)	K-114 Button (B) (TS)	8610004360	1
13	K-114 Button (D) (PRIO)	8610004380	1
(4)	K-114 Button (C) (HI/LO)	8610004370	1
(15)	N-131 Control Knob	8610004410	2
16	Included with		–
1	K-112 Button	8610004320	2
18	Push Spring (H)	8930006450	2
(19)	671 Switch Plate	8930013030	1
20	Sub-Chassis	8010007280	1
21	Tuning Control SRBM1L038A	2260000880	1
22	PH B0 2×5	8810000990	3
23	LED Spacer	8930012790	1
24	671 Grounding Plate	8930013330	1
25	671 LCD Reflector	8010007520	1
26	VR Nut (E)	8830000550	3
Ø	LCD Contact Strip SRCN543	8930012660	1
28	543 LCD Filter	8930012670	1
29	LCD 9811J	5030000330	1
30	543 LCD Holder-1	8930012681	1
31	671 LCD Rubber	8930013420	1
32	Set Screw (A) 2.6 × 5	8810003960	4
33	Mic Connector Assembly 8S-S-E	6510000290	1
34)	543 Mic Spacer	8930012430	1
35	SQUELCH CONTROL RK0971114005A	7210001490	1
36	VOLUME CONTROL RK097111200BA	7210001480	1

Screw typeScrew: M2.6 × 4, etc.Self-tapping screw: B0 2 × 4, etc.Screw's head stylePH: Pan headFH: Flat head

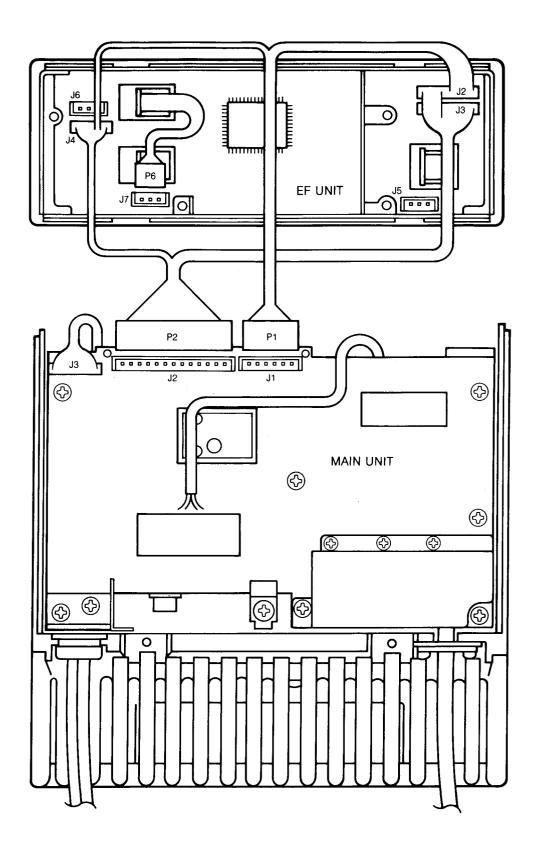
5-2 FRAME DISASSEMBLY



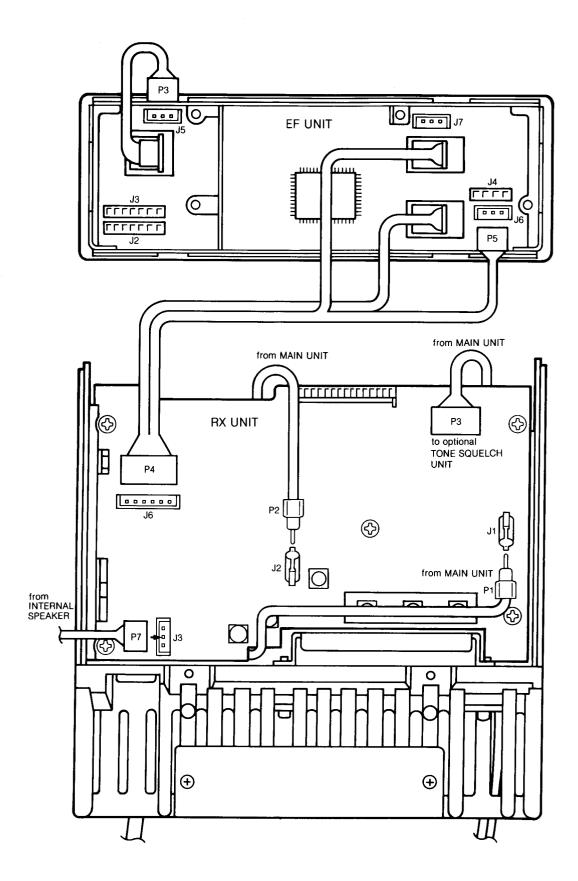
LABELLED NUMBER	DESCRIPTION	ORDER NUMBER	QTY.
37)	57 Speaker Holder	8930002650	1
38	Speaker 57S38-1	2510000280	1
39	57 Speaker Spacer	8930004950	1
	495 Bottom Cover (B)-1 (IC-228A/E)	8110002140	1
40	301 Bottom Cover (B)-1 (IC-228H)	8110002080	1
41	ICOM Screw (B) 4	8810003700	2
42	FH M2.6×5 ZK	8810002450	4
43	Set Screw (A) 3×5	8810003150	5
44	FH M3×8	8810002180	2
45	AF Heatsink (A)	8410000980	1
46	Spring Washer M3 Ni	8850000420	2
47)	Nut M3	8830000100	2
0	470 Chassis (A)-3 (IC-228A/E)	8110007511	1
48	301 Chassis (A)-4 (IC-228H)	8010007431	1
49	Cover Slider	8930000820	4
6	ICOM Screw (A) 12 (IC-228A/E)	8810004030	2
50	Set Screw (A) 3 × 18 (IC-228H)	8810003230	2
(51)	Power Supply Cable OPC-143 (Connector included)	8900001520	1
5 2	Module Shield Plate	8510003450	1
53	Rubber Bushing	8930007860	1
64	PH M3×6 BSBM Ni	8810001910	2
55	Antenna Cable OPC-186 (Connector included)	8900001890	1
56	Antenna Plate	8930009080	1
57	Set Screw (A) 3×5	8810003150	9
58	Mixer Shield Case	8510000470	1
59	Filter Shield Case	8510003070	1
60	Set Screw (A) 2.6 × 5	8810003960	3
61)	Mixer Shield Case	8510002020	1
62	VCO Case (A)	8510002210	1
63	VCO Top Cover (A)	8510002250	1
64	FH M3×5	8810002160	4

Screw typeScrew: M2.6 × 4, etc.Self-tapping screw: B0 2 × 4, etc.Screw's head stylePH: Pan headFH: Flat head

5-3 MAIN UNIT CONNECTOR ASSEMBLY



5-4 RX UNIT CONNECTOR ASSEMBLY



SECTION 6 MAINTENANCE AND ADJUSTMENT

6-1 PREPARATION BEFORE SERVICING

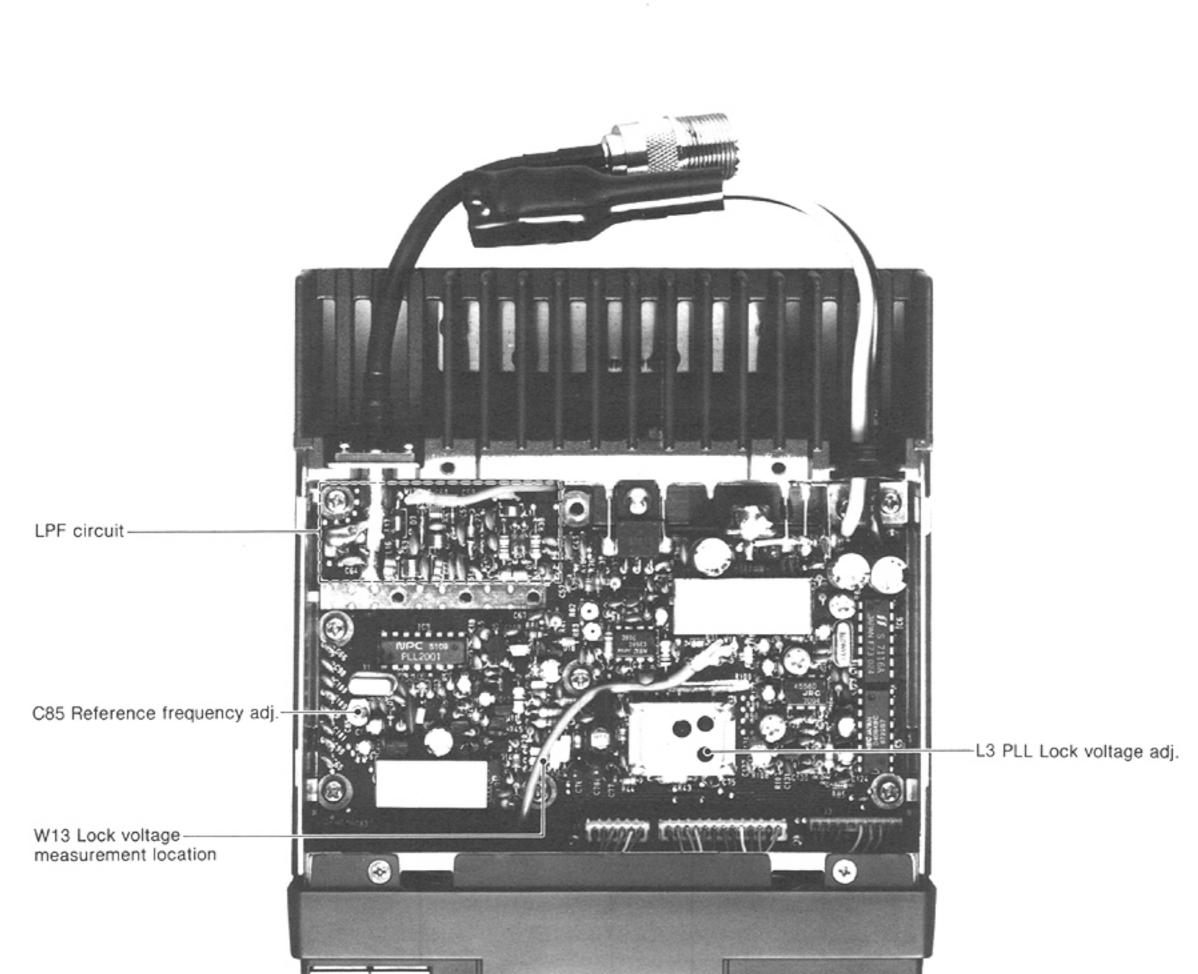
- 1. Detach the power cord and turn OFF the POWER SWITCH before performing any work on the transceiver.
- 2. DO NOT force any of the variable components. Turn them slowly and smoothly.
- 3. Follow the instructions exactly. If an indicated result is not obtained, repeat the instruction until the correct result is obtained.
- 4. Confirm defective operation of the transceiver first when checking an out-of-service unit. Verify that external sources DO NOT cause the problem.
- 5. Remove the transceiver case as shown in SECTION 5-1.

- For transmission problems, attach a dummy load to the ANTENNA CONNECTOR. For reception problems, attach an antenna or signal generator to the ANTENNA CONNECTOR. DO NOT transmit into the signal generator.
- 7. Re-check for the suspected malfunction with the POWER SWITCH ON.
- There are different versions of this transceiver. Adjustment procedures and results may differ for each version. Be sure to follow the correct procedure for the transceiver you adjust.

. т	EST I	NSTRUMENTS REQUIRED		MEASUREMENT CONNECTION LOCATION						
 (1) AC POWE Output Current (2) DC VOLT Input in 	voltaç capa METE	ge : 13.8V DC±15% city : 10A or more R	[RF POWER METER		AC POWER SUPPLY				
 (3) FREQUEI Frequei Frequei Sensitiv (4) RF POWE Minimu Frequei 	NCY (ncy m ncy ad /ity ER ME m pov ncy m	COUNTER inimum : 150MHz ccuracy : 1 ppm or better		FREQUENCY COUNTER	W13 MAIN UNIT IC-228A/E/H	DC VOLTMETER				
			MEASUREMENT			ADJUSTMENT POINT				
ADJUSTMI	ENT	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST			
LOCK VOLTAGE	1	• Frequency display: 145.000 MHz	MAIN	Connect the DC voltmeter to W13.	8V	MAIN (VCO)	L3			
REFERENCE FREQUENCY	1	Frequency display: 145.000 MHz Transmitting	MAIN	Loose couple the frequency counter to the LPF circuit.	145.000 MHz	MAIN	C85			

6-2 PLL ADJUSTMENT

MAIN UNIT



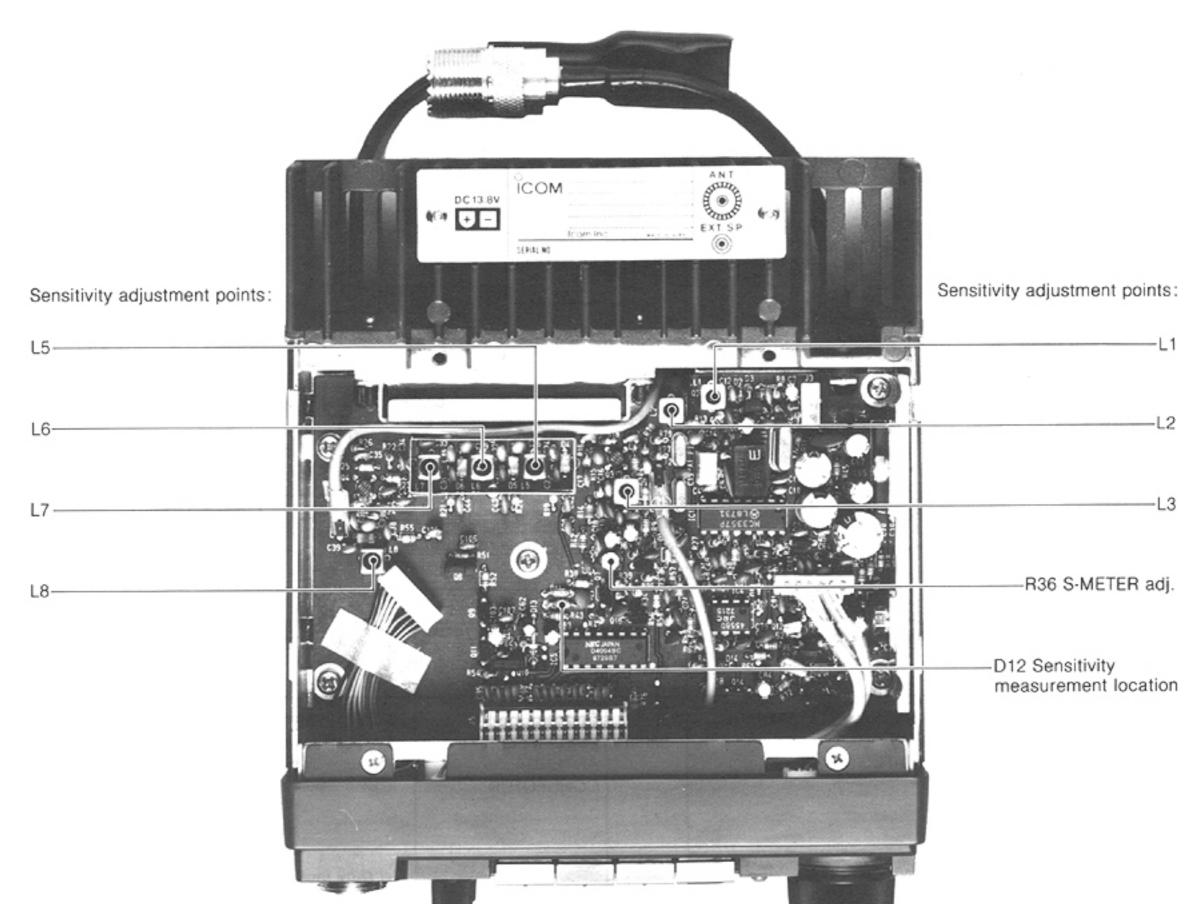
.



6-3 RECEIVER ADJUSTMENT

т	EST I	INSTRUMENTS REQUIRED	MEASUREMENT CONNECTION LOCATION						
 (1) AC POWE Output v Current (2) STANDAF Frequer Output I (3) DC VOLTI Input im 	voltag capa RD SI ncy ra level METE	ge : 13.8V DC±15% acity : 10A or more GNAL GENERATOR ange : 0.1~180 MHz : -127~-17 dBm (0.1μV~32mV)		AC POWER SUPPLY	STANDARD SIGNAL GENERATOF DC VOLTMETEF				
			M	EASUREMENT		ADJUSTMENT POINT			
ADJUSTME	NT	ADJUSTMENT CONDITIONS	UNIT	LOCATION	VALUE	UNIT	ADJUST		
SENSITIVITY	1	 Frequency display: 145.000 MHz Receiving Apply an RF signal to the ANTENNA CONNECTOR. Level: -97 dBm (3.16µV) Dev. : ±3.5kHz Mod. : 1 kHz R36: Max. counterclockwise 	RX	Connect the DC voltmeter to the cathode of D12.	Maximum	RX	Adjust in sequence L8 L7 L6 L5 Repeat above adjust- ments 2 or 3 times.		
	2	• Apply an RF signal to the ANTENNA CONNECTOR. Level: -97dBm (3.16µV) Dev. : ±7kHz					L3 L2 L1		
		NOTE: Adjust the signal generator out full scale reading of the lowest		ime until the DC voltn	neter is at 30% on the				
S-METER	1	 Frequency display: 145.000 MHz Receiving Apply an RF signal to the ANTENNA CONNECTOR. Level: -107 dBm (1μV) Dev. : ±3.5 kHz Mod. : 1 kHz 	FUNCTION DISPLAY	S/RF INDICATOR	S3 (2 dots)	RX	R36		

RX UNIT





*

6 — 4

.

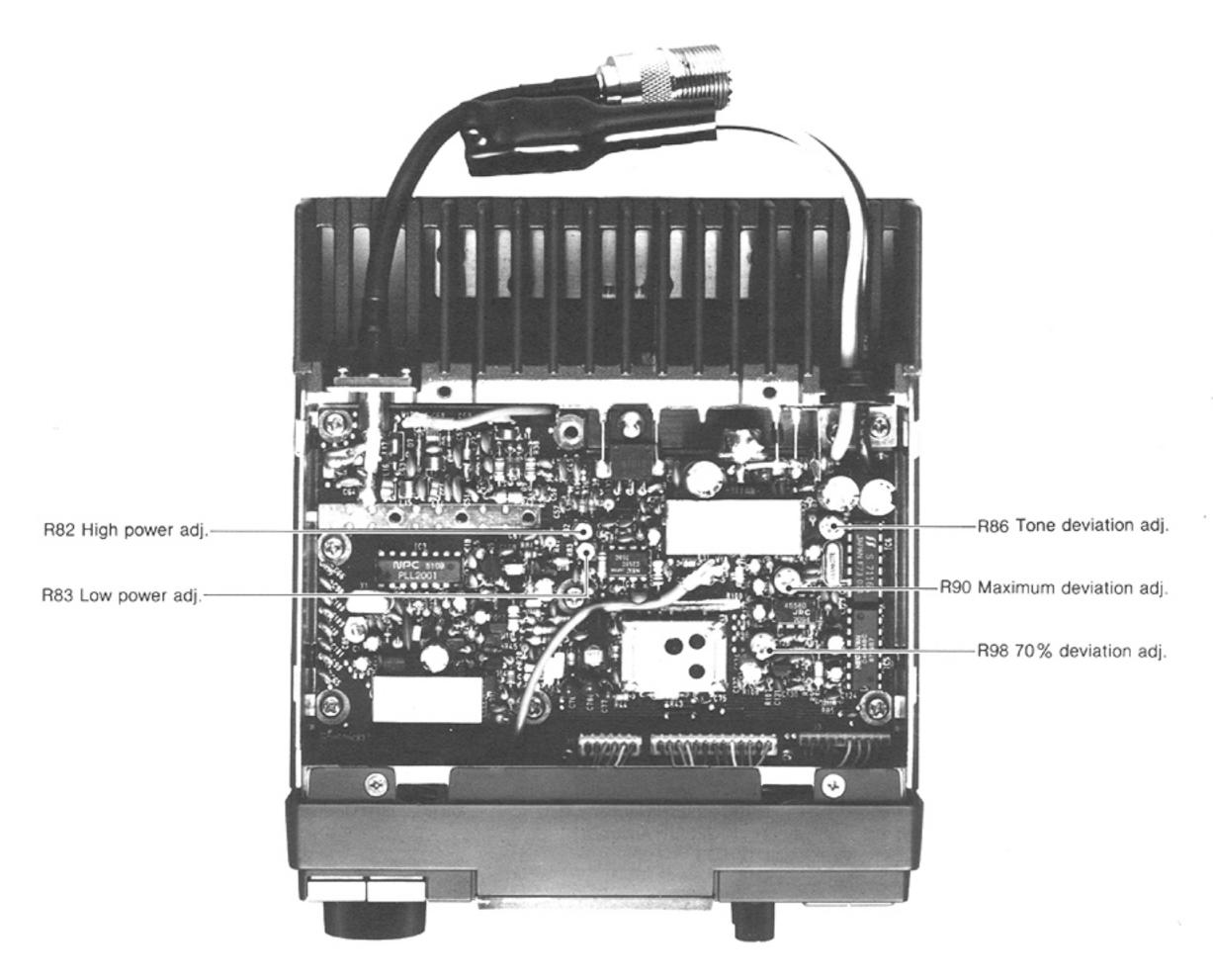
6-4 TRANSMITTER ADJUSTMENT

Т	EST I	NSTRUMENTS REQUIRED		MEASUREMEN	T CONNECTION LOCA	TION	
 Freque Input in SWR (3) FM DEVI 	volta t capa ER ME ated t m poo ncy m npeda ATION ncy m ing ra RATC ncy ra range ATOR	ge : $13.8 \text{V DC} \pm 15\%$ icity : 10A or more ETER ype wer rating: 50W inimum : 150MHz nce : 50Ω : $1.2:1 \text{ or better}$ I METER inimum : 150MHz nge : $0 \sim \pm 10 \text{ kHz}$ IR inge : $200 \sim 2000 \text{ Hz}$: $2 \sim 200 \text{ mV}$: $40 \text{ dB or 50 \text{ dB}}$			MAIN UNIT	TT9 /6	MIC NIC GND SWITCH
ADJUSTME	ADJUSTMENT ADJUSTMENT CONDITIONS		N	IEASUREMENT	VALUE	ADJUSTMENT POINT	
OUTPUT	1	• Frequency display: 145.000 MHz	UNIT	LOCATION Connect the RF	25W (IC-228A/E)	MAIN	ADJUST
POWER		Transmitting [HI/LO] SWITCH: HIGH	panel	power meter to the ANTENNA CONNECTOR.	45W (IC-228H)		
	2	•[HI/LO] SWITCH: LOW			5W (Any model)	- -	R83
DEVIATION		 Frequency display: 146.000 MHz (IC-228E/H Europe: 145.000 MHz) Transmitting Apply an AF signal to the MIC CONNECTOR Level: 20mV/1kHz (IC-228A/H U.S.A. 65mV/1kHz) Set the FM deviation meter. HPF: 50Hz LPF: 20kHz [T/T. SQL] SWITCH: OFF 	Rear panel	Connect the FM deviation meter to the ANTENNA CONNECTOR via the attenuator.	±4.8 kHz	MAIN	R90
	2	Apply an AF signal to the MIC CONNECTOR Level: 2mV/1kHz (IC-228A/H U.S.A. 6.5mV/1kHz)			±3.5kHz	MAIN	R98

TRANSMITTER ADJUSTMENT (CONTINUED)

ADJUSTME	NT	ADJUSTMENT CONDITIONS	N	IEASUREMENT	VALUE	ADJUSTMENT POINT		
ADDOOTMENT		ADJUSTMENT CONDITIONS	UNIT LOCATION		VALUE	UNIT	ADJUST	
TONE DEVIATION (IC-228A/H U.S.A., Asia only)	1	 Frequency display: 146.000 MHz Apply no signal to the MIC CONNECTOR. [T/T. SQL] SWITCH: ON Tone frequency: 88.5 kHz Set the FM deviation meter. HPF: OFF LPF: 20 kHz 	Rear panel	Connect the FM deviation meter to the ANTENNA CONNECTOR via the attenuator.	±0.85kHz	MAIN	R86	
POWER MODULE INPUT (For repair reference)	1	 Frequency display: 145.000 MHz Remove solder and disconnect IC1 pin 1 from MAIN UNIT. Transmitting 	MAIN	Connect the RF power meter (1 W type) to the point where solder is removed.	More than +26dBm (400mW) (IC-228H) More than +23dBm (200mW) (IC-228A/E)		Verify	

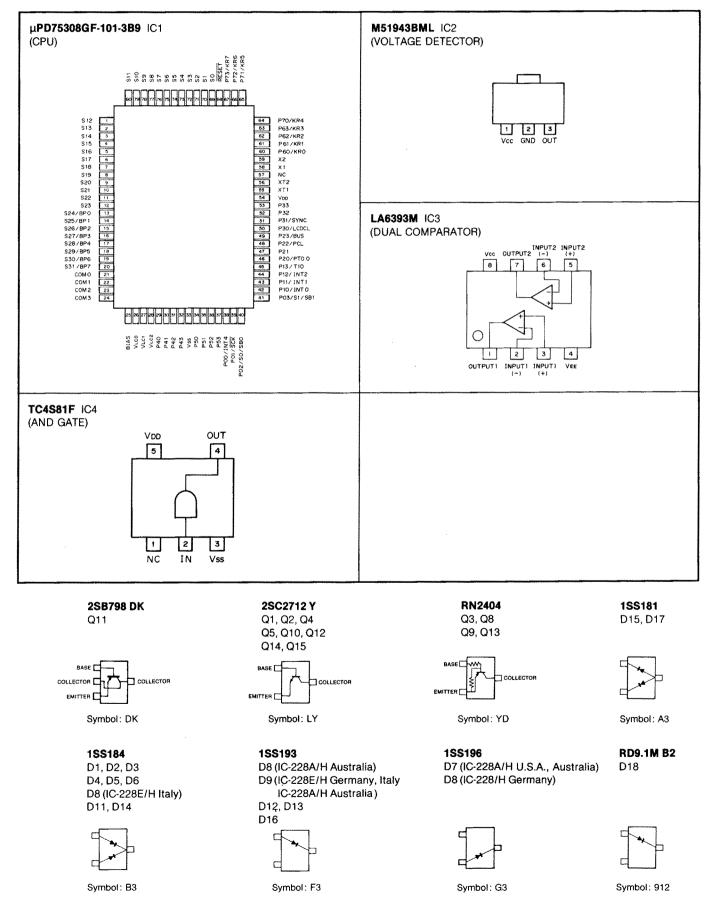
MAIN UNIT



SECTION 7 BOARD LAYOUTS

7-1 EF UNIT

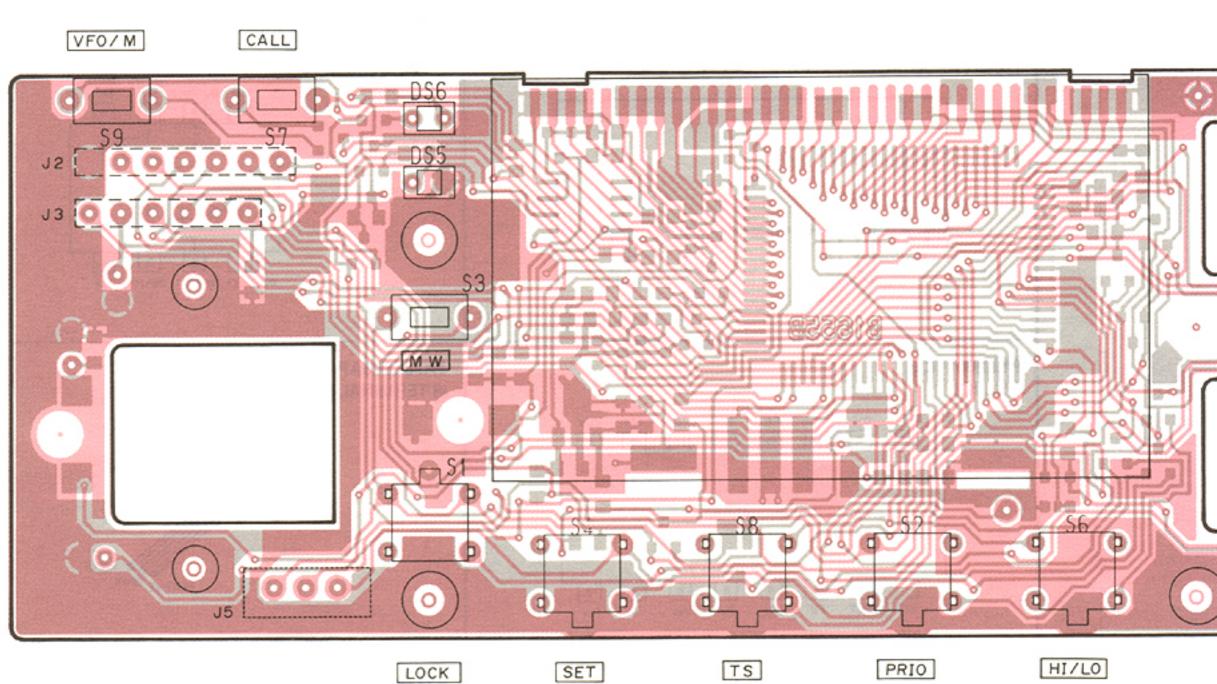
• EF UNIT



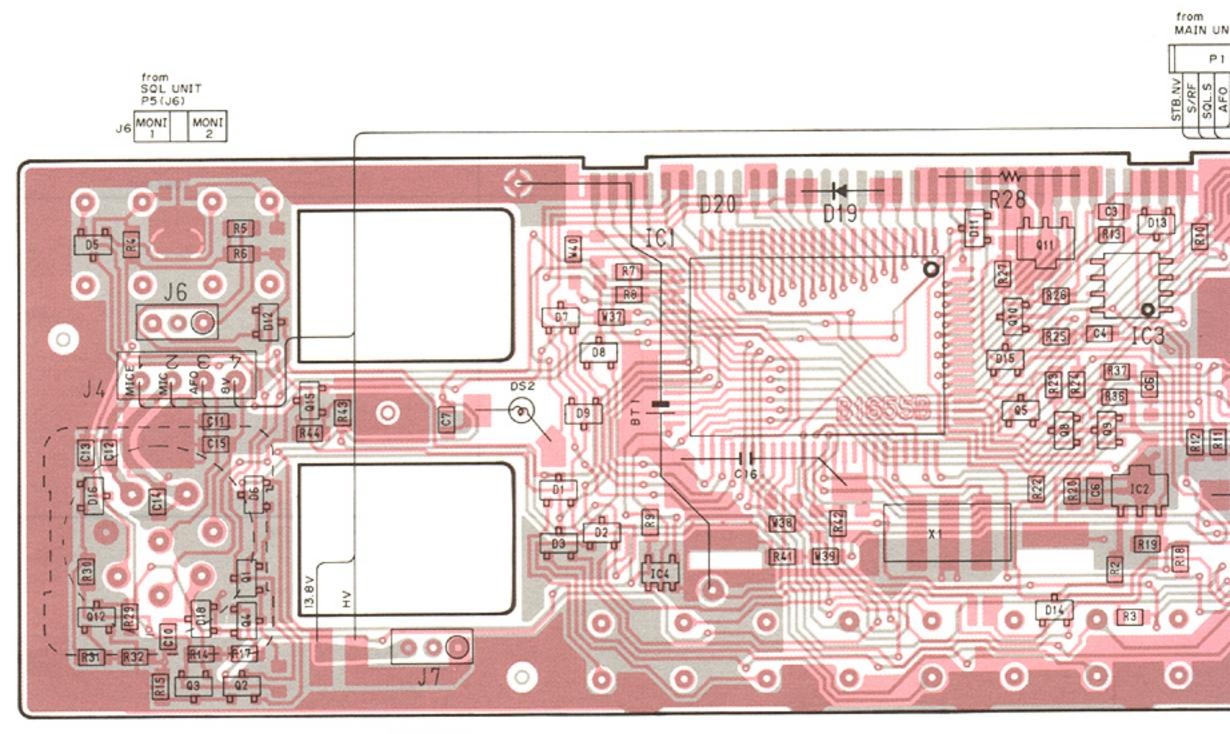
7 - 1

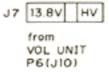
EF UNIT

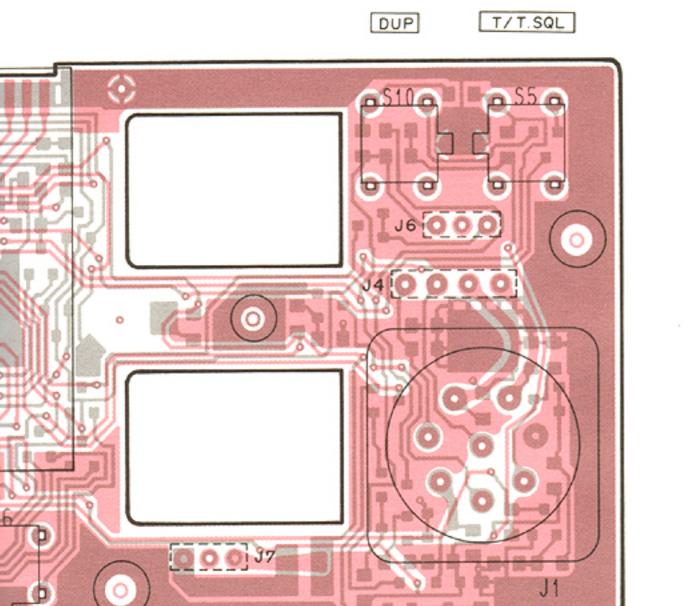
COMPONENT SIDE



FOIL SIDE

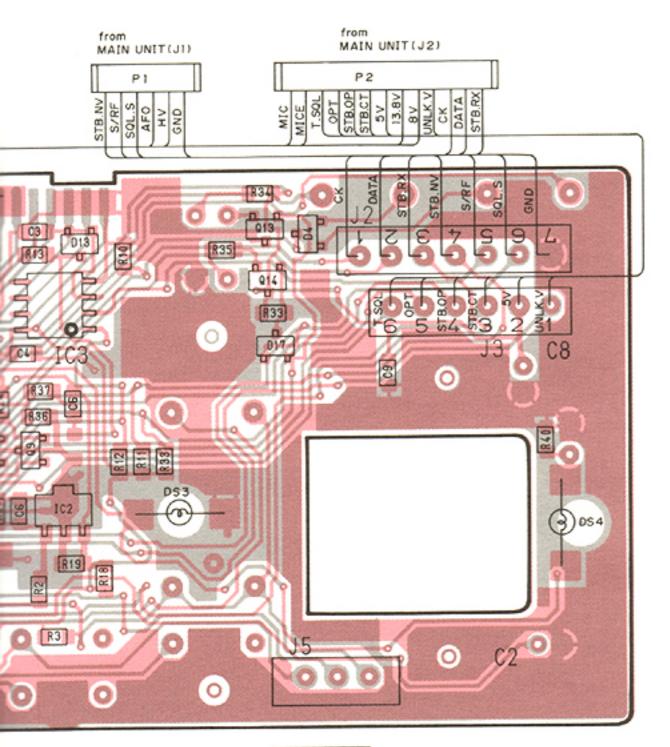




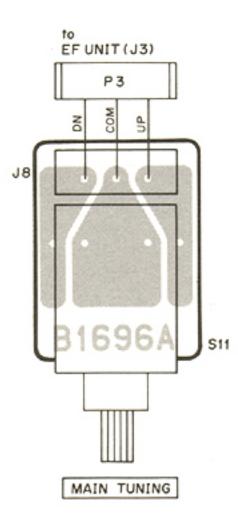


MICROPHONE CONNECTOR

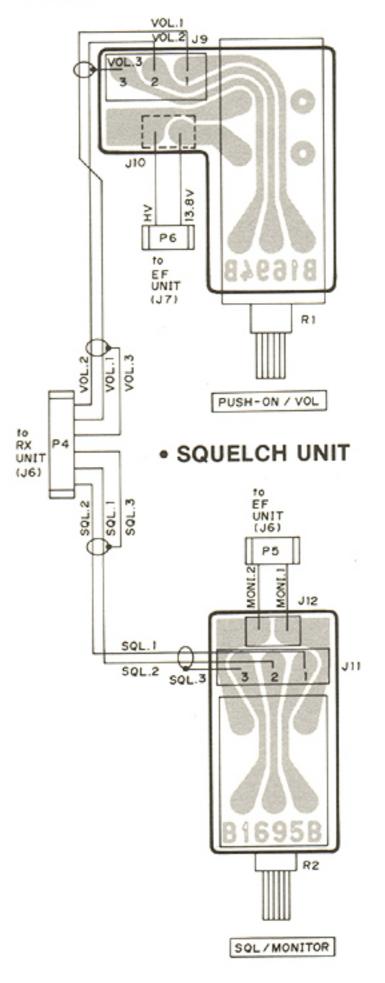
1/L0



SENSOR UNIT



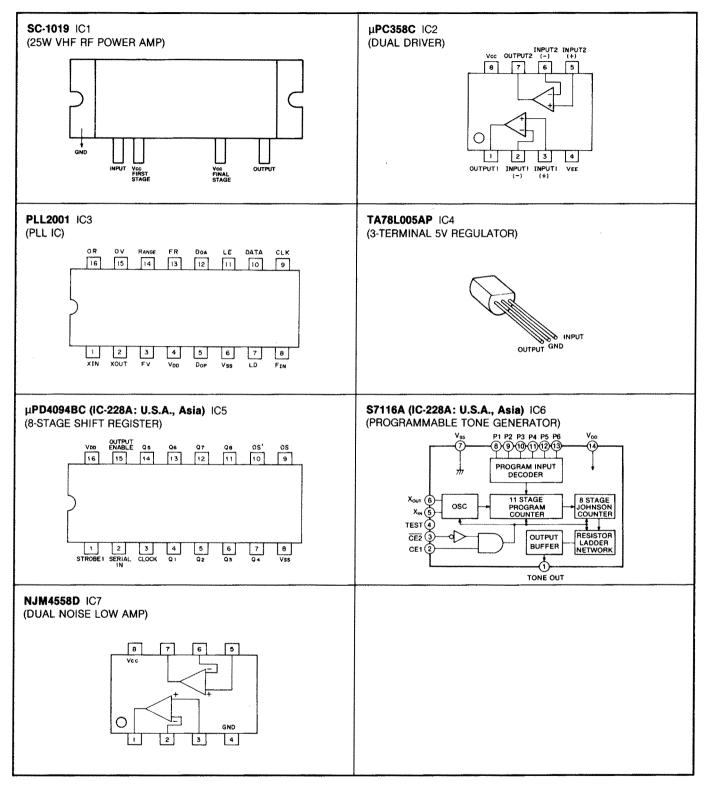
VOLUME UNIT



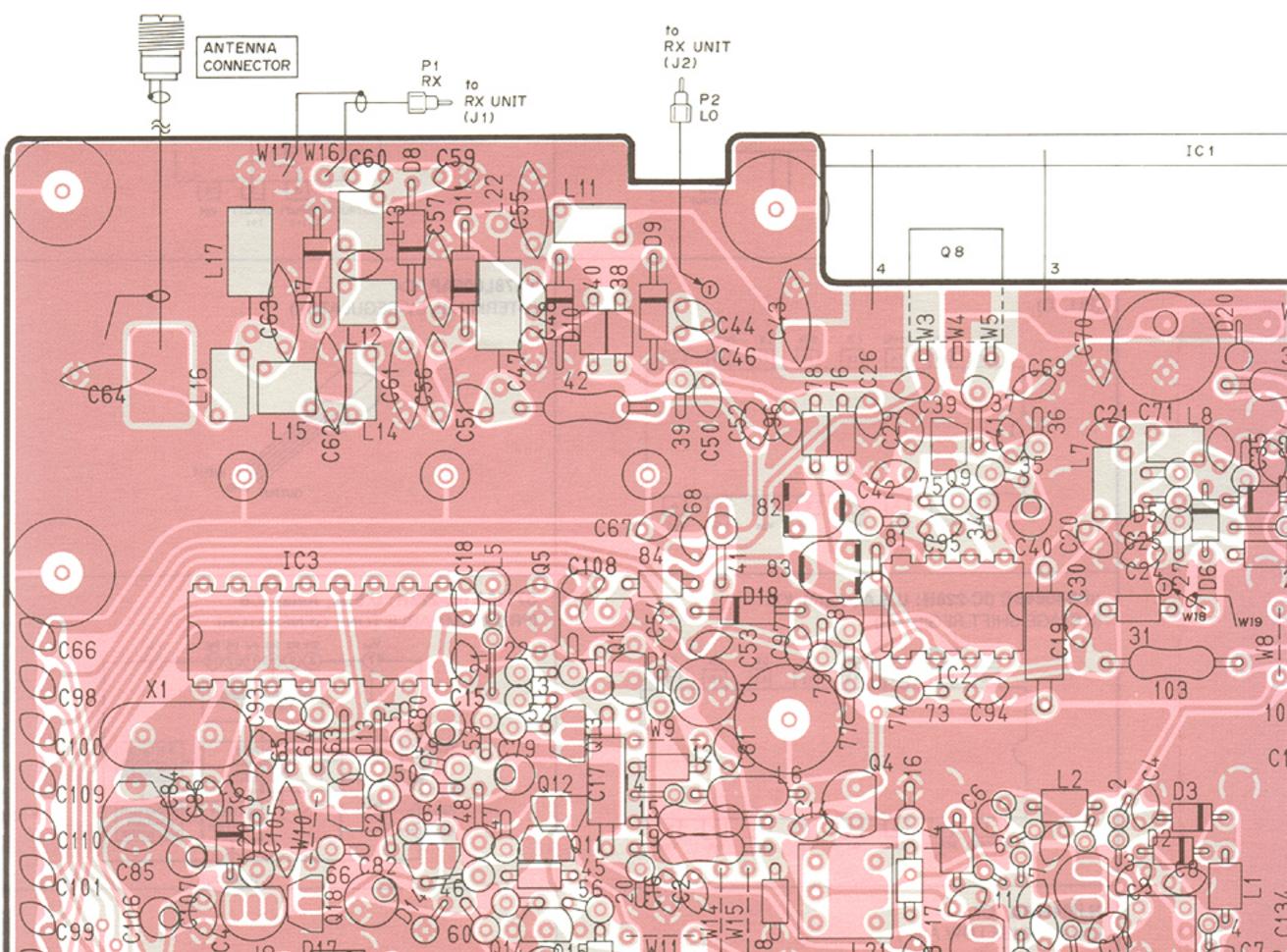
J5 UP COM DN from VOL UNIT P3(J8)

7-2 MAIN UNIT

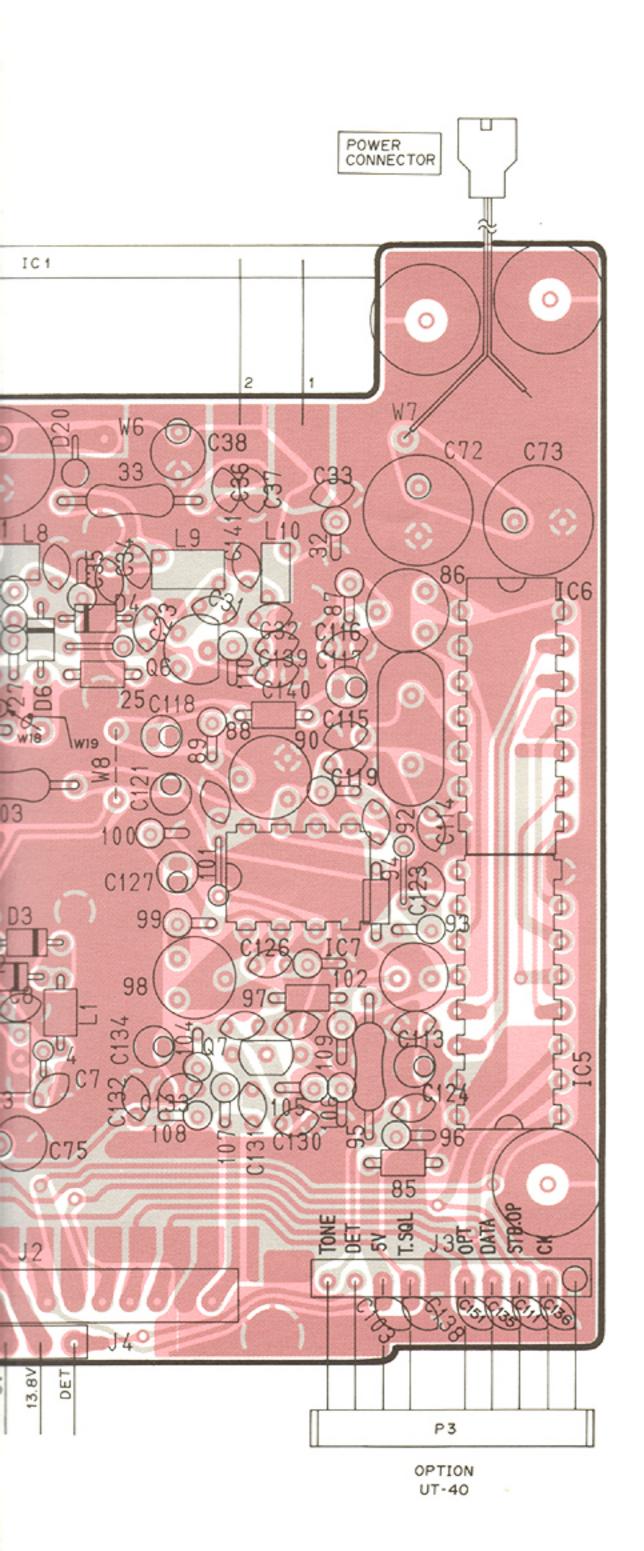
• IC-228A/E

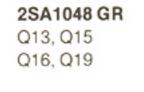


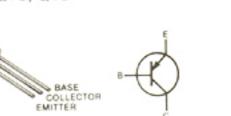
• MAIN UNIT (IC-228A/E)



				L3 0 C7 9 0 C75 J2
J1	J2	LAND SIND	ILO B.R B.R CK	BV S.BV
GND HV AFO SQL. S/RF NV	STB. DATA CK UNLK. 8V 13.8V 5V STB. STB. OPT T.S	from	HI/LO TUNE STB.R DATA CK	13.0 DE
FRONT FRONT \ FRONT UNIT UNIT from UNIT P1(J2) P1 FRONT P1(J2) UNIT P1(J4)	FRONT from from FRONT FRONT UNIT FRONT FRONT UNIT UNIT P2(J2) UNIT UNIT P2 P2(J3) P2(J3) P2(J4)	FRONT UNIT P2(J4)	to RX UNIT (J5)	













RN1204 Q10

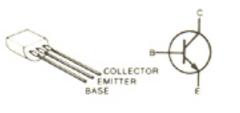








2SK125 Q2



GATE SOURCE

2SC2458 GR Q1, Q9 Q12, Q17 Q18, Q20 2SC2458L G

2SK184 Y Q11, Q14



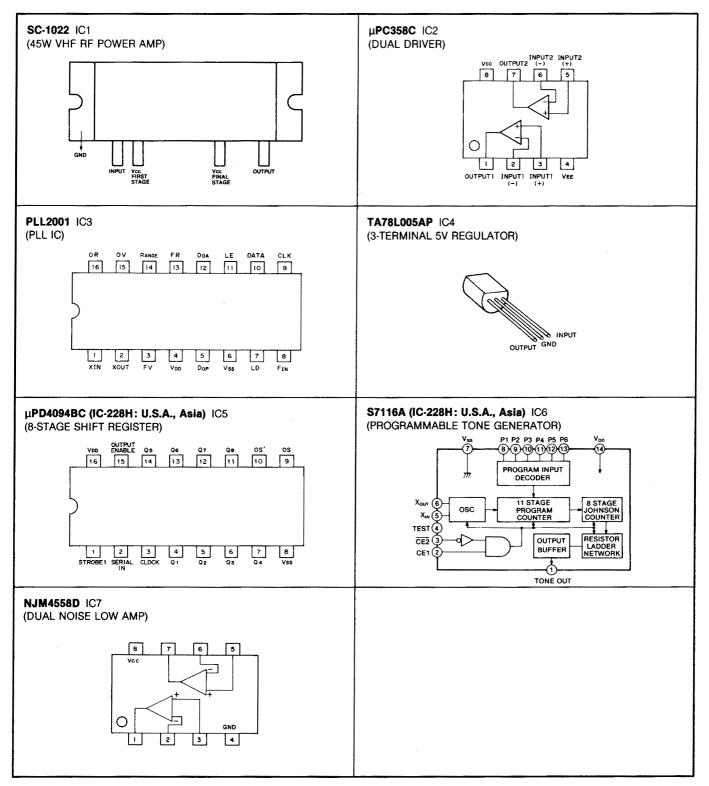


Q7

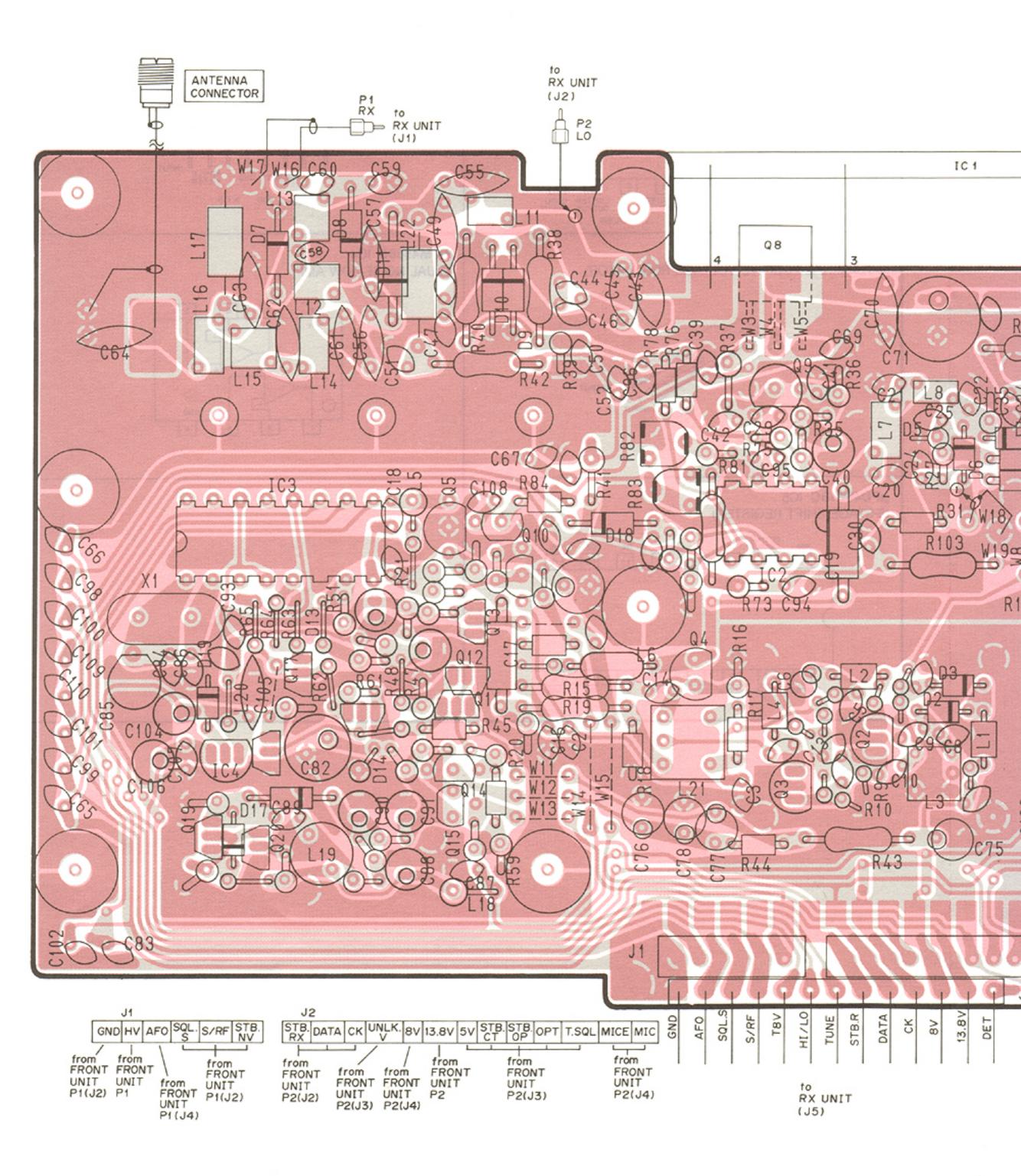
7 — 4

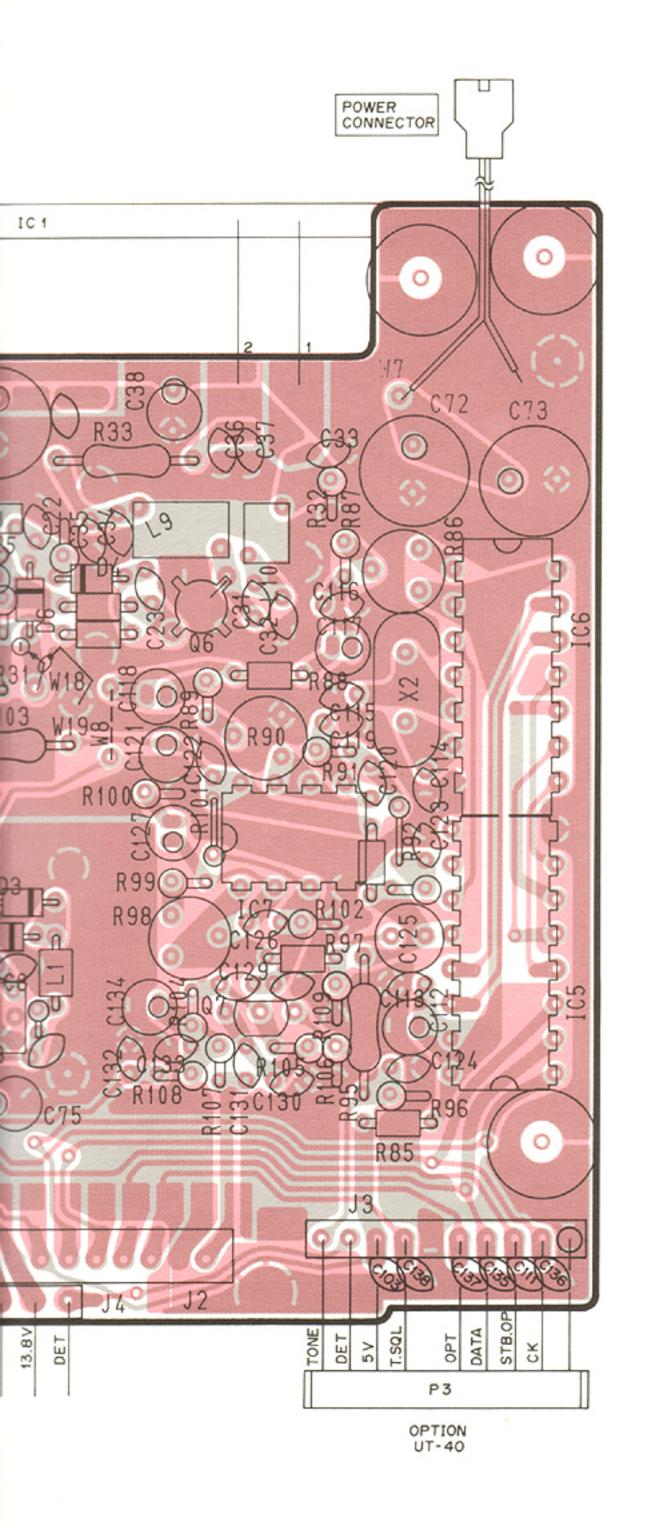
5

• IC-228H



• MAIN UNIT (IC-228H)





2SA1048 GR Q13, Q15 Q16, Q19



RN1204







(P)

COLLECTOR





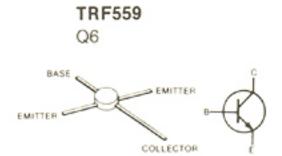
2SC1645 B Q9 BASE COLLECTOR EMITTER

> 2SC2458 GR Q1, Q12 Q17, Q18 Q20 2SC2458L G Q7



2SK184 Y Q11, Q14

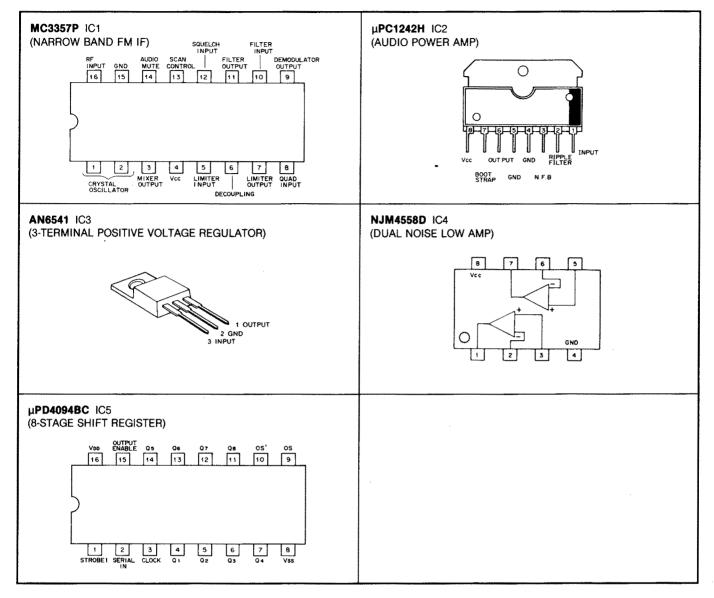


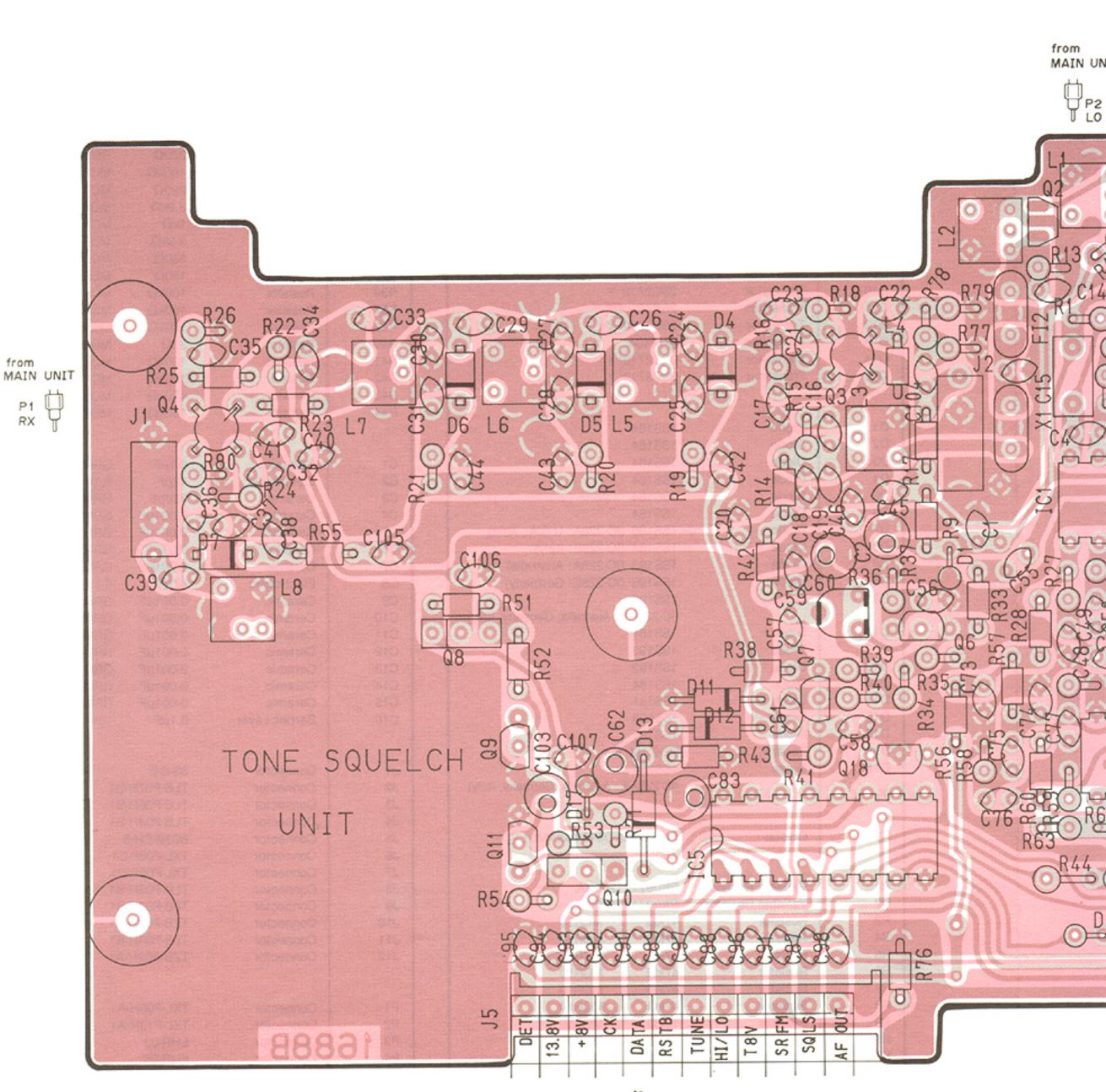


2SC3776 D Q3, Q4 Q5

COLLECTOR EMITTER BASE

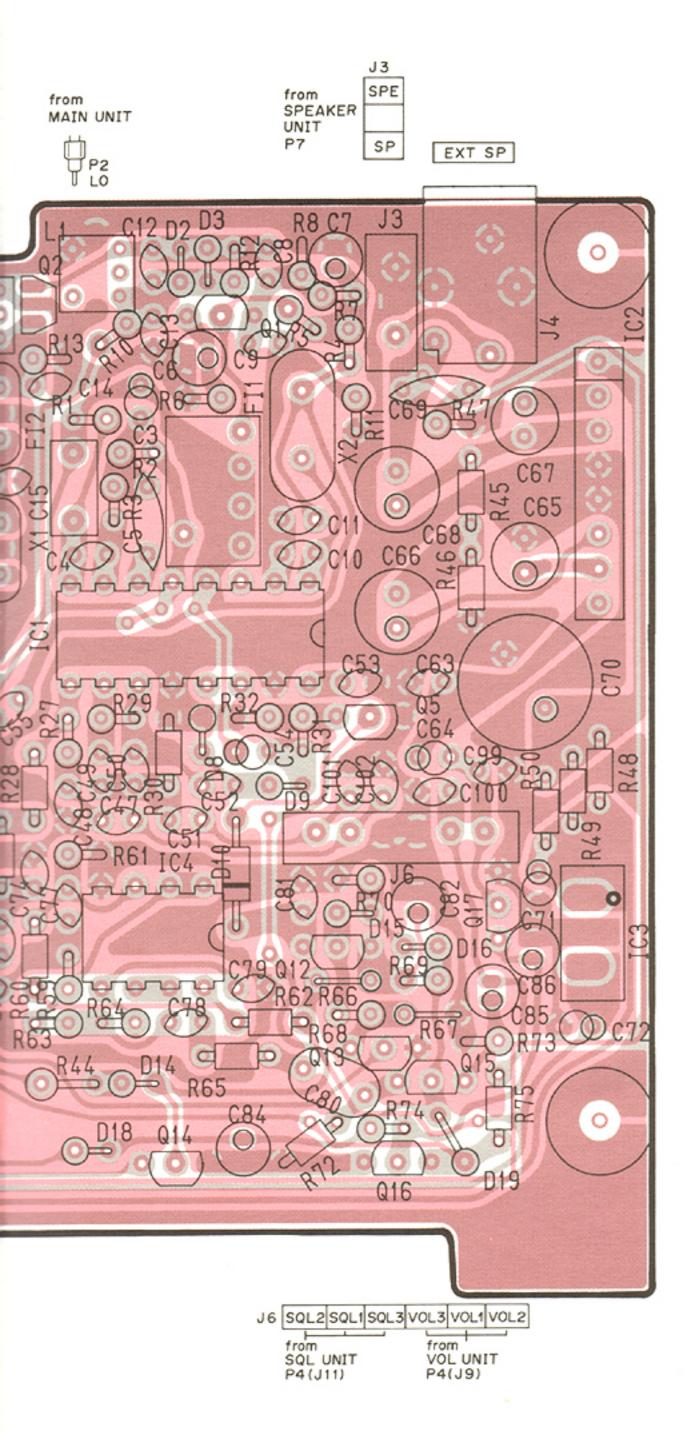
7-3 RX UNIT



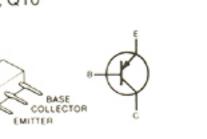


RX UNIT

to MAIN UNIT (J4)



2SB909M Q/R Q8, Q10





RN2204

Q12, Q18

2SC2458 GR Q5, Q6 Q7, Q13

2SJ105 GR Q15



2SC2668 O Q1

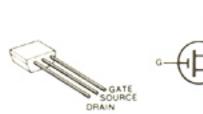
2SK241 GR Q2



COLLECTOR EMITTER

RN1204 Q9, Q11 Q14, Q16 Q17







3SK174 L Q3, Q4



SECTION 8 PARTS LIST

[EF UNIT]

- 	-	· · · · · · · · · · · · · · · · · · ·
REF. NO.	DESCRIPTION	PART NO.
IC1	IC	µPD75308GF-101-3B9
IC2	IC	M51943BML
1C3		
IC4		TC4S81F
Q1	Transistor	2SC2712 Y
Q2	Transistor	2SC2712 Y
Q3	Transistor	RN2404
Q4	Transistor	2SC2712 Y
Q5	Transistor Transistor	2SC2712 Y
Q8 Q9	Transistor	RN2404 RN2404
Q10	Transistor	2SC2712 Y
Q11	Transistor	2SB798 DK
Q12	Transistor	2SC2712 Y
Q13 Q14	Transistor Transistor	RN2404 2SC2712 Y
Q15	Transistor	2SC2712 Y
D1	Diode	1SS184
D2 D3	Diode Diode	1SS184 1SS184
D3 D4	Diode	1SS184
D5	Diode	1SS184
D6	Diode	1SS184
D7	Diode	1SS196 (IC-228A: U.S.A., Asia)
D8 D8	Diode Diode	1SS184 (IC-228E: Italy) 1SS193 (IC-228A: Australia)
D8	Diode	1SS196 (IC-228E: Germany)
D9	Diode	1SS193
	Diada	(IC-228A/E: Australia, Germany, Italy)
D11 D12	Diode Diode	1SS184 1SS193
D13	Diode	1SS193
D14	Diode	1SS184
D15	Diode	1SS181
D16 D17	Diode Diode	1SS193 1SS181
D18	Zener	RD9.1M B2
D19	Diode	1SS254
		(IC-228A/E: Australia, Germany, Italy)
X1	Crystal	FAR-C4CA-04194000-M01
R1	Variable Resistor	RK097111200BA
R2	Variable Resistor	RK097111200BA RK0971114005A
R3	Resistor	47kΩ MCR10
R4	Resistor	47kΩ MCR10
R5 R6	Resistor Resistor	47kΩ MCR10 47kΩ MCR10
R7	Resistor	47kΩ MCR10
R8	Resistor	47kΩ MCR10
R9	Resistor	15kΩ MCR10
R10	Resistor	1MΩ MCR10 8.2kΩ MCR10
R11 R12	Resistor Resistor	8.2κΩ MCR10 100kΩ MCR10
R13	Resistor	$1.2M\Omega$ MCR10
R14	Resistor	1kΩ MCR10
R15	Resistor Resistor	100kΩ MCR10
R16 R17	Resistor Resistor	100kΩ MCR10 100kΩ MCR10
R18	Resistor	4.7kΩ MCR10
R19	Resistor	220kΩ MCR10
R20 R21	Resistor Resistor	3.3kΩ MCR10 2.7kΩ MCR10
R22	Resistor	82kΩ MCR10

[EF UNIT]

REF. NO.	DESCRIPTION	PART	NO.
R23	Resistor	27k Ω	MCR10
R24	Resistor	56kΩ	MCR10
R25	Resistor	27k Ω	MCR10
R26	Resistor	1.2 kΩ	MCR10
R27	Resistor	1.8kΩ	MCR10
R28	Resistor	220 Ω 100k Ω	R50X MCR10
R29 R30	Resistor Resistor	220 Q	MCR10
R31	Resistor	220 Ω 3.9kΩ	MCR10
R32	Resistor	1kΩ	MCR10
R33	Resistor	3.3kΩ	MCR10
R34	Resistor	330 Ω	MCR10
R35	Resistor	180 Ω	MCR10
R36	Resistor	100k Ω	MCR10
R37	Resistor	100kΩ	MCR10
R39	Resistor	100kΩ	MCR10
R40	Resistor	33Ω	MCR10
R41	Resistor	100kΩ	MCR10
R42	Resistor Resistor	100kΩ 470kΩ	MCR10 MCR10
R43 R44	Resistor	470kΩ 150kΩ	MCR10
H44	nesistor	TOUKSZ	MONTO
C1	Ceramic	0.1µF	GRM40 F
C2	Electrolytic	47μF	6.3V MS7
C3	Ceramic	330pF	GRM40 CH
C4	Ceramic	0.001µF	GRM40
C5	Ceramic	0.001µF	GRM40
C6	Ceramic	0.01µF	GRM40 F
C7	Ceramic	0.001µF	GRM40
C8	Electrolytic	47µF	6.3V MS7
C9	Ceramic	0.001µF	GRM40
C10	Ceramic	0.001µF	GRM40
C11	Ceramic	0.001µF	GRM40
C12	Ceramic	0.001µF	GRM40
C13	Ceramic	0.001µF	GRM40
C14	Ceramic	0.001µF	GRM40
C15	Ceramic	0.001µF	GRM40
C16	Barrier Layer	0.1µF	16V
J1	Connector	8S-S-E	
J2	Connector	TLB-P07H-I	B1
J3	Connector	TLB-P06H-I	
J4	Connector	TLB-P04H-I	31
J5	Connector	B03B-EH-S	
J6	Connector	TXL-P03P-C	21
J7	Connector	TXL-P03P-C	
J8	Connector	TLB-P03H-I	
J9	Connector	TLB-P03H-I	
J10	Connector	TZB-P02H-/	
J11	Connector	TLB-P03H-I	
J12	Connector	TZB-P02H-/	A 1
P1	Connector	TXL-P06H-A	1
P1 P2	Connector Connector	TXL-P06H-/	
P2 P3	Connector	EHR-03	11
P3 P4	Connector	EHR-03	
P5	Connector	TXL-P03H-A	A1
P6	Connector	TXL-P03H-A	
P7	Connector	EHR-03	
DS1	LCD	LCD-9811J	
DS2	Lamp	HRS-7219A	
DS3	Lamp	HRS-7219A	
DS4	Lamp	HRS-7219A	-12 30
DS5	LED	SLP-251B	
DS6	LED	SLP-151B	

[EF UNIT]

REF. NO.	DESCRIPTION	PART NO.
S1	Switch	SKHHAK013A
S2	Switch	HKW0270-01-300
S3	Switch	SKHLAB064A
S4	Switch	HKW0270-01-300
S5	Switch	HKW0270-01-300
S6	Switch	HKW0270-01-300
S7	Switch	SKHLAB064A
S8	Switch	HKW0270-01-300
S9	Switch	SKHLAB064A
S10	Switch	HKW0270-01-300
S11	Rotary Encoder	SRBM1L038A
SP1 BT1	Speaker Lithium Battery	57S38-1
EP1	P.C. Board	B-1655B (LOGIC)
EP1 EP2	P.C. Board P.C. Board	, ,
EP3	P.C. Board	B-1695B (SQUELCH)
EP4	P.C. Board	B-1696A (SENSOR)
EP5	LCD Contact Strip	

[MAIN UNIT]

REF. NO.	DESCRIPTION	PART NO.
IC1	IC	SC-1019 (IC-228A/E)
		SC-1022 (IC-228H)
IC2	IC	μPC358C
IC3	IC	PLL2001
IC4	IC	TA78L005AP
IC5	I IC	µPD4094BC (IC-228A: U.S.A., Asia)
IC6	IC	S7116A (IC-228A: U.S.A., Asia)
IC7	IC	NJM4558D
Q1	Transistor	2SC2458 GR
Q2	FET	2SK125
Q3	Transistor	2SC3776 D
Q4	Transistor	2SC3776 D
Q5	Transistor	2SC3776 D
Q6	Transistor	2SC2407 (IC-228A/E)
		TRF559 (IC-228H)
Q7	Transistor	2SC2458L G
Q8	Transistor	2SA1359 Y (IC-228A/E)
		2SB1019 (IC-228H)
Q9	Transistor	2SC2458 GR (IC-228A/E)
		2SC1645 B
Q10	Transistor	RN1204
Q11	FET	2SK184 Y
Q12	Transistor	2SC2458 GR
Q13	Transistor	2SA1048 GR
Q14	FET	2SK184 Y
Q15	Transistor	2SA1048 GR
Q16	Transistor	2SA1048 GR
Q17	Transistor	2SC2458 GR
Q18	Transistor	2SC2458 GR
Q19	Transistor	2SA1048 GR
Q20	Transistor	2SC2458 GR
D1	Diode	18853
D2	Varicap	1SV50E
D3	Varicap	1SV50E
D4	Diode	1SS265
D5	Diode	1SS53
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REF. NO.	DESCRIPTION	PART NO.
D6	Diode	1SS265
D7 D8	Diode Diode	M1308 M1308
D9	Diode	1SS97
D10	Diode	1SS97
D11	Diode	MI308 (IC-228A/E)
540	Diada	MI407 (IC-228H)
D12 D13	Diode Diode	15CD11 1SS53
D13	Zener	RD20E B2
D15	Diode	1SS133
D16	Diode	18953
D17 D18	Zener Diode	RD30E B2 1SS53
D19	Diode	1SS133
X1	Crystal	CR-69
X2	Crystal	RF4A3FAA (IC-228A: U.S.A., Asia)
1.1	Coil	3.3µH LAL02KR 3R3K
L1 L2	Coil Coil	3.3μ H LALO2KH 3H3K 3.3µH LALO2KH 3H3K
L3	Coil	LB-167
L4	Coil	3.3µH LAL02KR 3R3K
L5	Coil	3.3µH LALO3NA 3R3K 3.3µH LALO3NA 3R3K
L6 L7	Coil Coil	LA-244
L8	Coil	LA-234
L9	Coil	LA-244 (IC-228A/E)
		LA-254 (IC-228H)
L10	Coil	LA-233 (IC-228A/E) LA-235 (IC-228H)
L11	Coil	LA-234
L12	Coil	LA-235
L13	Coil	LA-235
L14 L15	Coil Coil	LA-243 LA-236
L15	Coil	LA-244
L17	Coil	LW-19
L18	Coil	1mH LAL03NA 102K
L19 L20	Coil Coil	LW-30 100µH LAL03NA 101K
L20	Coil	LR-116
L22	Coil	LW-19
D1	Desister	4.7k Ω ELR20
R1 R2	Resistor Resistor	4.7kΩ ELR20 2.7kΩ ELR20
R3	Resistor	470Ω ELR20
R4	Resistor	470Ω ELR20
R5	Resistor Resistor	47 Ω ELR20 47 Ω ELR20
R6 R7	Resistor	100Ω ELR20
R8	Resistor	4.7k Ω ELR20
R9	Resistor	220 Ω ELR20
R10	Resistor	680Ω ELR20 47Ω ELR20
R11 R12	Resistor Resistor	$4/\Omega$ ELR20 100 Ω R20
R13	Resistor	100 Ω ELR20
R14	Resistor	47Ω ELR20
R15	Resistor	4.7kΩ R25
R16 R17	Resistor Resistor	680Ω ELR20 47Ω R20
R18	Resistor	270 Ω R20
R19	Resistor	18Ω R25
R20	Resistor	270Ω ELR20
R21 R22	Resistor Resistor	47 Ω ELR20 4.7k Ω ELR20
R22	Resistor	680Ω ELR20
R24	Resistor	3.3kΩ ELR20
R25	Resistor	1kΩ R20
R26 R27	Resistor Resistor	47 Ω ELR20 2.2k Ω ELR20
R31	Resistor	390 Ω R20

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50V (IC-228A/E) 50V (IC-228H) 50V 35V

500V (IC-228A/E) 500V (IC-228H) 50V (IC-228A/E) 50V UJ (IC-228H) 500V (IC-228H only) 50V CH (IC-228A/H) 50V CH (IC-228H) 50V CH (IC-228A/H) 50V CH (IC-228H) 50V (IC-228A/E) 50V UJ (IC-228H) 500V (IC-228H only)

RH0651C15J1UA ELR20 ELR20 ELR20 ELR20 R25 ELR20 ELR20 ELR20 ELR20 ELR20 ELR20

ELR20 (IC-228A/E only) ELR20 (IC-228A/E only)

REF. NO.	DESCRIPTION	PAR	RT NO.		REF. NO.	DESCRIPTION	PAR	T NO.
R32	Resistor	150Ω	ELR20	1	R97	Resistor	150kΩ	R20
33	Resistor	10Ω	R25		R98	Trimmer	100kΩ	RH0651C15J
34	Resistor	10kΩ	ELR20		R99	Resistor	1.5k Ω	ELR20
35	Resistor	47kΩ	ELR20		R100	Resistor	100Ω	ELR20
					R101	Resistor	220kΩ	ELR20
R36	Resistor	33kΩ	ELR20			1		ELR20
37	Resistor	330 Ω	R50X (IC-228A/E)		R102	Resistor	270kΩ	
		220Ω	R50X (IC-228H)		R103	Resistor	100Ω	R25
38	Resistor	4.7kΩ	R20		R104	Resistor	5.6kΩ	ELR20
		4.7kΩ	CRB25FX (IC-228H)		R105	Resistor	1.2MΩ	ELR20
39	Resistor	4.7kΩ	ELR20		R106	Resistor	330 Ω	ELR20
840	Resistor	4.7kΩ	R20 (IC-228A/E)		R107	Resistor	1kΩ	ELR20
		4.7kΩ	CRB25FX (IC-228H)		R108	Resistor	100 Ω	ELR20
R41	Resistor	47Ω	R50X (IC-228A/E)		R109	Resistor	4.7kΩ	ELR20
		33Ω	R50X (IC-228H)		R110	Resistor	10Ω	ELR20 (IC-22
42	Resistor	47Ω	R50X (IC-228A/E)		R111	Resistor	330 Ω	ELR20 (IC-22
+2	nesision				0111	116313101	00012	
	–	33 Ω	R50X (IC-228H)					
43	Resistor	2.2kΩ	R25	1	_			
}44	Resistor	270 Ω	R20		C1	Electrolytic	100µF	10V SS
45	Resistor	10kΩ	R20	1	C2	Ceramic	470pF	50V
346	Resistor	1kΩ	ELR20		C3	Ceramic	0.001µF	50V
847	Resistor	100kΩ	ELR20	1	C4	Ceramic	470pF	50V
48	Resistor	270kΩ	ELR20	1	C5	Ceramic	470pF	50V
49	Resistor	220kΩ	ELR20		C6	Tantalum	4.7µF	16V DN
149	Resistor			1	C7	Ceramic	470pF	50V
1		4.7kΩ	ELR20	1			•	
151	Resistor	15kΩ	ELR20	1	C8	Ceramic	1pF	50V
752	Resistor	56k Ω	ELR20		C9	Ceramic	0.001µF	50V
753	Resistor	270k Ω	ELR20	1	C10	Ceramic	0.001µF	50V
755	Resistor	220kΩ	ELR20		C11	Ceramic	1pF	50V
356	Resistor	2.2 MΩ	ELR20		C12	Ceramic	100pF	50V
857	Resistor	10Ω	R20		C13	Ceramic	470pF	50V
158	Resistor	150kΩ	ELR20		C14	Ceramic	22pF	50V
150	Resistor	100kΩ	ELR20		C15	Ceramic	470pF	50V
			ELR20		C16	Ceramic	470pF	50V
160	Resistor	6.8kΩ						
761	Resistor	220kΩ	ELR20	1 1	C17	Cylinder		25 SL 220J
362	Resistor	56kΩ	ELR20	1	C18	Ceramic	5pF	50V
63	Resistor	47kΩ	ELR20	1 1	C19	Cylinder		125 SL 5R6K
364	Resistor	220kΩ	ELR20		C20	Ceramic	10pF	50V
865	Resistor	100kΩ	ELR20		C21	Ceramic	22pF	50V
766	Resistor	47kΩ	ELR20		C22	Ceramic	12pF	50V
67	Resistor	15kΩ	ELR20		C23	Ceramic	20pF	50V (IC-228A
168	Resistor	2.2kΩ	ELR20				30pF	50V (IC-228H
769	Resistor	68kΩ	ELR20		C24	Ceramic	470pF	50V
70	Resistor	10kΩ	ELR20		C25	Ceramic	470pF	50V
71	Resistor	470 Ω	ELR20		C26	Ceramic	470pF	50V
	Resistor	470Ω 470Ω	ELR20	1	C20 C29	Ceramic	470pf	50V
772				F			470pF 470pF	50V 50V
873	Resistor	100 Ω	ELR20		C30	Ceramic		
874	Resistor	15kΩ	R25		C31	Ceramic	22pF	50V
75	Resistor	2.2MΩ	ELR20		C32	Ceramic	10pF	50V
76	Resistor	56kΩ	R20		C33	Ceramic	22pF	50V
77	Resistor	680Ω	ELR20		C34	Ceramic	470pF	50V
78	Resistor	10kΩ	R20	1	C35	Ceramic	0.001µF	50V
79	Resistor	100kΩ	ELR20	1 1	C36	Ceramic	470pF	50V
180	Resistor	180kΩ	ELR20	I	C37	Ceramic	0.001µF	50V
81	Resistor	1.2kΩ	ELR20 (IC-228A/E)		C38	Tantalum	10µF	35V DN
· • ·		1kΩ	ELR20 (IC-228H)		C39	Ceramic	470pF	50V
82	Trimmer	3.3kΩ	RH0421CN3J01A		C39 C40	Electrolytic	470pi 10μF	16V MS7
							0.001 µ F	50V
83	Trimmer	2.2kΩ	RH0421CJ3J09A		C41	Ceramic	•	
184	Resistor	390 Ω	R20 (IC-228A/E)		C42	Ceramic	0.001µF	50V
		47Ω	R20 (IC-228H)	1	C43	Ceramic	22pF	500V (IC-228/
785	Resistor	10 Ω	R20	1			12pF	500V (IC-228
		(IC-228A:	U.S.A., Asia)	1	C44	Ceramic	1pF	50V (IC-228A
786	Resistor	47kΩ R⊢	10651CS4J25A				2pF	50V UJ (IC-2
			U.S.A., Asia)	FI	C45	Ceramic	2pF	500V (IC-228)
87	Resistor	47kΩ	ELR20		C46	Ceramic	20pF	50V CH (IC-2
			U.S.A., Asia)		2.2	_ = . =	27pF	50V CH (IC-2
188	Posistor	(IC-226A. 47kΩ	R20		C47	Ceramic	20pF	50V CH (IC-2
100	Resistor				047	Ocianile		50V CH (IC-2
	Desister		U.S.A., Asia)		0.40	0	27pF	
89	Resistor	5.6kΩ	ELR20		C48	Ceramic	1pF	50V (IC-228A
90	Trimmer	10kΩ	RH0651C14J2WA	İ	ł		2pF	50V UJ (IC-2
91	Resistor	82kΩ	ELR20		C49	Ceramic	2pF	500V (IC-228)
92	Resistor	82kΩ	ELR20		C50	Ceramic	0.001µF	50V
3	Resistor	82kΩ	ELR20		C51	Ceramic	0.001µF	50V
4	Resistor	150kΩ	R20		C52	Ceramic	470pF	50V
			R25		C52 C53	Ceramic	470pF 0.001μF	50V 50V
5	Resistor	47k Ω		I	C53 C54	Ceramic	470pF	
196	Resistor	100kΩ	ELR20					50V

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C55 Ceramic 12pF 500V C56 Ceramic 0.001µF 500V C57 Ceramic 22pF 500V (IC-228A/E) C58 Ceramic 39pF 50V C59 Ceramic 20pF 50V C60 Ceramic 100pF 50V C61 Ceramic 30pF 500V C62 Ceramic 30pF 500V C63 Ceramic 0.001µF 50V C64 Ceramic 0.001µF 50V C65 Ceramic 0.001µF 50V C66 Ceramic 0.001µF 50V C67 Ceramic 0.001µF 50V C68 Ceramic 0.001µF 50V C70 Ceramic 330µF 16V SS C71 Electrolytic 330µF 16V SS C72 Electrolytic 330µF 16V SS C73 Tantalum 0.0µF 35V </th <th></th>	
C57 Ceramic $22pF$ $500V$ (IC-228/JE) C58 Ceramic $39pF$ $50V$ C59 Ceramic $20pF$ $50V$ C60 Ceramic $100pF$ $50V$ C61 Ceramic $30pF$ $500V$ C62 Ceramic $30pF$ $500V$ C63 Ceramic $30pF$ $500V$ C64 Ceramic $0.01\muF$ $50V$ C66 Ceramic $0.001\muF$ $50V$ C67 Ceramic $0.001\muF$ $50V$ C68 Ceramic $0.001\muF$ $50V$ C70 Ceramic $200FF$ $50V$ C71 Electrolytic $330\muF$ $16V$ SS C73 Electrolytic $330\muF$ $16V$ SS C74 Feed Through $0.01\muF$ $35V$ DN C75 Tantalum $0.0\muF$ $35V$ DN C76 Tantalum $10\muF$ $35V$ DN <td></td>	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	
C58 Ceramic 39pF 50V C59 Ceramic 20pF 50V C60 Ceramic 10pF 50V C61 Ceramic 30pF 500V C62 Ceramic 30pF 500V C63 Ceramic 30pF 500V C64 Ceramic 0.001 μ F 50V C66 Ceramic 470pF 50V C66 Ceramic 0.001 μ F 50V C67 Ceramic 0.001 μ F 50V C68 Ceramic 0.001 μ F 50V C70 Ceramic 200F 50V C71 Electrolytic 330 μ F 16V SS C73 Electrolytic 330 μ F 16V SS C74 Feed Through 0.01 μ F 35V DN C75 Tantalum 10 μ F 35V DN C76 Tantalum 10 μ F 50V KS3 C88	
C59 Ceramic 20pF 50V C60 Ceramic 15pF 500V C61 Ceramic 30pF 500V C62 Ceramic 30pF 500V C63 Ceramic 30pF 500V C64 Ceramic 10pF 50V C66 Ceramic 0.001µF 50V C66 Ceramic 0.001µF 50V C68 Ceramic 0.001µF 50V C68 Ceramic 0.001µF 50V C70 Ceramic 200F 50V C71 Electrolytic 330µF 16V SS C72 Electrolytic 330µF 16V SS C74 Feed Through 0.001µF TS18.450E 102GMV C75 Tantalum 10µF 35V DN C76 Tantalum 10µF 35V DN C77 Entalum 10µF 50V MS7 C81 <	
C60 Ceramic 100pF 50V C61 Ceramic 30pF 500V C62 Ceramic 30pF 500V C63 Ceramic 30pF 500V C64 Ceramic 10pF 500V C65 Ceramic 0.001 μ F 50V C66 Ceramic 470pF 50V C68 Ceramic 0.001 μ F 50V C68 Ceramic 0.001 μ F 50V C70 Ceramic 0.001 μ F 50V C71 Electrolytic 330 μ F 16V SS C72 Electrolytic 330 μ F 16V SS C74 Feed Through 0.001 μ F T38-450E 102GMV C75 Tantalum 10 μ F 35V DN C76 Tantalum 10 μ F 35V DN C77 Tantalum 10 μ F 50V KS7 C81 Ceramic 22 μ F 50V KS7	
C61 Ceramic 15pF 500V C62 Ceramic 30pF 500V C63 Ceramic 30pF 500V C64 Ceramic 10pF 50V C65 Ceramic 470pF 50V C66 Ceramic 470pF 50V C67 Ceramic 0.001 μ F 50V C68 Ceramic 0.001 μ F 50V C69 Ceramic 0.001 μ F 50V C70 Ceramic 30 μ F 16V SS C71 Electrolytic 330 μ F 16V SS C73 Electrolytic 330 μ F 16V SS C74 Feed Through 0.01 μ F Tsta-450E 102GMV C75 Tantalum 10 μ F 35V DN C76 Tantalum 10 μ F 35V DN C77 Tantalum 10 μ F 5V MS7 C80 Electrolytic 4.7 μ F	
C63 Ceramic 30pF 500V C64 Ceramic 10pF 500V C65 Ceramic 0.001 μ F 50V C66 Ceramic 470pF 50V C67 Ceramic 0.001 μ F 50V C68 Ceramic 0.001 μ F 50V C69 Ceramic 0.001 μ F 50V C70 Ceramic 220pF 50V C71 Electrolytic 330 μ F 16V SS C72 Electrolytic 330 μ F 16V SS C73 Electrolytic 330 μ F 16V SS C74 Feed Through 0.01 μ F 35V DN C75 Tantalum 10 μ F 35V DN C76 Tantalum 10 μ F 35V DN C77 Tantalum 10 μ F 35V DN C79 Electrolytic 4.7 μ F 25V MS9 C83 Ceramic 20pF	
C64 Ceramic 10pF 500V C65 Ceramic 0.001 μ F 50V C66 Ceramic 470pF 50V C68 Ceramic 0.001 μ F 50V C68 Ceramic 0.001 μ F 50V C69 Ceramic 220pF 50V C70 Ceramic 230 μ F 16V SS C71 Electrolytic 330 μ F 16V SS C73 Electrolytic 330 μ F 16V SS C74 Feed Through 0.01 μ F 35V DN C75 Tantalum 10 μ F 35V DN C77 Tantalum 10 μ F 50V KS7 C80 Electrolytic 1 μ F 50V MS7 C81 Cera	
C65 Ceramic 0.001μ F 50V C66 Ceramic 470pF 50V C67 Ceramic 0.001 μ F 50V C68 Ceramic 470pF 50V C69 Ceramic 2001 μ F 50V C70 Ceramic 220pF 50V C71 Electrolytic 330 μ F 16V SS C72 Electrolytic 330 μ F 16V SS C73 Electrolytic 330 μ F 16V SS C74 Feed Through 0.001 μ F TS18-450E 102GMV C75 Tantalum 10 μ F 35V DN C76 Tantalum 10 μ F 35V DN C77 Tantalum 10 μ F 35V DN C79 Electrolytic 4.7μ F 25V MS7 C80 Electrolytic 1 μ F 50V S3 C83 Ceramic 20pF 50V C84 Ceramic<	
C66 Ceramic 470pF 50V C67 Ceramic 0.001 μ F 50V C68 Ceramic 470pF 50V C69 Ceramic 0.001 μ F 50V C70 Ceramic 220pF 50V C71 Electrolytic 330 μ F 16V SS C72 Electrolytic 330 μ F 16V SS C73 Electrolytic 330 μ F 16V SS C74 Feed Through 0.01 μ F T318-450E 102GMN C75 Tantalum 10 μ F 35V DN C76 Tantalum 10 μ F 35V DN C77 Tantalum 10 μ F 35V DN C79 Electrolytic 47 μ F 25V MS7 C80 Electrolytic 47 μ F 25V MS9 C81 Ceramic 20pF 50V C83 Ceramic 20pF 50V C84 Ceramic 20pF </td <td></td>	
C67 Ceramic 0.01μ F $50V$ C68 Ceramic $470p$ F $50V$ C69 Ceramic 0.01μ F $50V$ C70 Ceramic $220p$ F $50V$ C71 Electrolytic 330μ F $16V$ SS C72 Electrolytic 330μ F $16V$ SS C73 Electrolytic 330μ F $16V$ SS C74 Feed Through 0.01μ F TS18-450E $102GMV$ C75 Tantalum 0.1μ F $35V$ DN C76 Tantalum 10μ F $35V$ DN C77 Tantalum 10μ F $35V$ DN C78 Tantalum 10μ F $50V$ MS7 C81 Ceramic 0.001μ F <td< td=""><td></td></td<>	
C68 Ceramic $470 pF$ $50V$ C69 Ceramic $0.001 \mu F$ $50V$ C70 Ceramic $220 pF$ $50V$ C71 Electrolytic $330 \mu F$ $16V$ SS C72 Electrolytic $330 \mu F$ $16V$ SS C73 Electrolytic $330 \mu F$ $16V$ SS C74 Feed Through $0.001 \mu F$ $35V$ DN C75 Tantalum $10 \mu F$ $35V$ DN C76 Tantalum $10 \mu F$ $35V$ DN C77 Tantalum $10 \mu F$ $35V$ DN C77 Tantalum $10 \mu F$ $35V$ DN C77 Tantalum $10 \mu F$ $35V$ DN C78 Tantalum $10 \mu F$ $35V$ DN C82 Electrolytic $47 \mu F$ $25V$ MS7 C83 Ceramic $20 pF$ $CV05D2001$ Ceas C84 Cer	
C70 Ceramic $220pF$ $50V$ C71 Electrolytic $330\muF$ $16V$ SS C72 Electrolytic $330\muF$ $16V$ SS C73 Electrolytic $330\muF$ $16V$ SS C74 Feed Through $0.01\muF$ $TF318-450E$ $102GMN$ C75 Tantalum $0.1\muF$ $35V$ DN C76 Tantalum $10\muF$ $35V$ DN C77 Tantalum $10\muF$ $35V$ DN C78 Tantalum $10\muF$ $50V$ MS7 C80 Electrolytic $1\muF$ $50V$ MS7 C81 Ceramic $20pF$ $50V$ C83 C83 Ceramic $0.01\muF$ $50V$ C84 C84 </td <td></td>	
C71 Electrolytic 330μ F $16V$ SS C72 Electrolytic 330μ F $16V$ SS C73 Electrolytic 330μ F $16V$ SS C74 Feed Through 0.001μ F TF318-450E $102GMV$ C75 Tantalum 0.1μ F $35V$ DN C76 Tantalum 10μ F $35V$ DN C77 Tantalum 10μ F $35V$ DN C78 Tantalum 10μ F $35V$ DN C79 Electrolytic 4.7μ F $25V$ MS7 C80 Electrolytic 47μ F $25V$ MS9 C81 Ceramic 22ρ F $50V$ C84 Ceramic 20ρ F $CV05D2001$ C86 C83 Ceramic 0.001μ F $50V$ C84 Ceramic 0.001μ F $50V$ C85 Trimmer 20ρ F $50V$ C86 Ceramic 0.001μ	
C72 Electrolytic 330μ F $16V$ SS C73 Electrolytic 330μ F $16V$ SS C74 Feed Through 0.001μ F TF318-450E $102GMN$ C75 Tantalum 0.1μ F $35V$ DN C76 Tantalum 10μ F $35V$ DN C77 Tantalum 10μ F $35V$ DN C78 Tantalum 10μ F $35V$ DN C79 Electrolytic 4.7μ F $25V$ MS7 C80 Electrolytic 4.7μ F $25V$ MS7 C81 Ceramic 0.001μ F $50V$ MS7 C82 Electrolytic 4.7μ F $25V$ MS9 C83 Ceramic $20p$ F $50V$ C86 C84 Ceramic 0.001μ F $50V$ C87 C85 Trimmer $20p$ F $50V$ MS7 C86 Ceramic 0.001μ F $50V$ MS7	
C73Electrolytic 330μ F $16V$ SSC74Feed Through 0.001μ FTF318-450E $102GMN$ C75Tantalum 0.1μ F $35V$ DNC76Tantalum 10μ F $35V$ DNC77Tantalum 10μ F $35V$ DNC78Electrolytic 4.7μ F $25V$ MS7C80Electrolytic 1μ F $50V$ MS7C81Ceramic 0.001μ F $50V$ C82C82Electrolytic 47μ F $25V$ MS9C83Ceramic $22p$ F $50V$ C85C84Ceramic $27p$ F $50V$ C86C87Ceramic 0.001μ F $16V$ MS7C88Electrolytic 10μ F $16V$ MS7C89Ceramic $100p$ F $50V$ MS7C91Electrolytic 3.3μ F $50V$ MS7C92Ceramic 0.001μ F $50V$ MS7C93Barrier Layer 0.01μ F $50V$ C96C94Ceramic 0.001μ F $50V$ C97C95Ceramic 0.001μ F $50V$ C98C99Ceramic 0.001μ F $50V$ C101Ceramic 0.001μ F $50V$ C103CeramicC99Ceramic 0.001μ F $50V$ C103C99Ceramic 0.001μ F $50V$ C103C99Ceramic 0.001μ F $50V$ C103C99Ceramic 0.001μ F $50V$ <td< td=""><td></td></td<>	
C74 Feed Through $0.001 \mu F$ TF318-450E $102GMV$ C75 Tantalum $0.1 \mu F$ $35V$ DN C76 Tantalum $10\mu F$ $35V$ DN C77 Tantalum $10\mu F$ $35V$ DN C78 Tantalum $10\mu F$ $35V$ DN C79 Electrolytic $4.7\mu F$ $25V$ MS7 C80 Electrolytic $4.7\mu F$ $25V$ MS7 C81 Ceramic $0.001\mu F$ $50V$ C82 Electrolytic $47\mu F$ $25V$ MS9 C83 Ceramic $18p F$ $50V$ C84 Ceramic $0.001\mu F$ $50V$ C85 Trimmer $20p F$ $50V$ C86 Ceramic $0.001\mu F$ $50V$ C87 Ceramic $0.001\mu F$ $50V$ C88 Electrolytic $3.3\mu F$ $50V$ MS7 C90 Electrolytic $3.3\mu F$ $50V$	
$\begin{array}{ccccc} -C75 & Tantalum & 0.1 \mu F & 35 V & DN \\ C76 & Tantalum & 10 \mu F & 35 V & DN \\ C77 & Tantalum & 2.2 \mu F & 35 V & DN \\ C78 & Tantalum & 10 \mu F & 35 V & DN \\ C79 & Electrolytic & 4.7 \mu F & 25 V & MS7 \\ C80 & Electrolytic & 1 \mu F & 50 V & MS7 \\ C81 & Ceramic & 0.001 \mu F & 50 V \\ C82 & Electrolytic & 47 \mu F & 25 V & MS9 \\ C83 & Ceramic & 22 \rho F & 50 V \\ C84 & Ceramic & 18 \rho F & 50 V \\ C85 & Trimmer & 20 \rho F & CV05 D 2001 \\ C86 & Ceramic & 27 \rho F & 50 V \\ C87 & Ceramic & 0.001 \mu F & 50 V \\ C88 & Electrolytic & 10 \mu F & 16 V & MS7 \\ C89 & Ceramic & 100 \rho F & 50 V \\ C90 & Electrolytic & 3.3 \mu F & 50 V & MS7 \\ C91 & Electrolytic & 3.3 \mu F & 50 V & MS7 \\ C92 & Ceramic & 0.001 \mu F & 50 V \\ C93 & Barrier Layer & 0.01 \mu F & 50 V \\ C94 & Ceramic & 0.001 \mu F & 50 V \\ C95 & Ceramic & 0.001 \mu F & 50 V \\ C96 & Ceramic & 0.001 \mu F & 50 V \\ C97 & Ceramic & 0.001 \mu F & 50 V \\ C98 & Ceramic & 0.001 \mu F & 50 V \\ C99 & Electrolytic & 3.3 \mu F & 50 V & MS7 \\ C91 & Electrolytic & 3.0 \mu F & 50 V \\ C93 & Barrier Layer & 0.01 \mu F & 50 V \\ C94 & Ceramic & 0.001 \mu F & 50 V \\ C95 & Ceramic & 0.001 \mu F & 50 V \\ C96 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C101 & Ceramic & 470 \rho F & 50 V \\ C102 & Ceramic & 470 \rho F & 50 V \\ C103 & Ceramic & 470 \mu F & 50 V \\ C104 & Electrolytic & 22 \mu F & 6.3 V & MS7 \\ C105 & Barrier Layer & 0.1 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 50 V \\ C107 & Ceramic & 0.001 \mu F & 50 V \\ C108 & Ceramic & 0.001 \mu F & 50 V \\ C109 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu$	v
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C78 Tantalum 10μ F $35V$ DN C79 Electrolytic 4.7μ F $25V$ MS7 C80 Electrolytic 1μ F $50V$ MS7 C81 Ceramic 0.001μ F $50V$ MS7 C81 Ceramic $22p$ F $50V$ MS9 C83 Ceramic $22p$ F $50V$ C84 Ceramic $27p$ F $50V$ C87 Ceramic $27p$ F $50V$ C84 Ceramic 0.001μ F $16V$ MS7 C88 Electrolytic 10μ F $16V$ MS7 C88 Electrolytic 3.3μ F $50V$ MS7 C91 Electrolytic 3.3μ F $50V$ MS7 C90 Electrolytic 3.3μ F $50V$ MS7 C92 Ceramic 0.001μ F $50V$ C93 Barrier Layer 0.1μ F $25V$ C94 Ceramic 0.001μ F $50V$ C95 Ceramic 0.001μ F $50V$ C96 </td <td></td>	
$\begin{array}{rcrcrc} C79 & Electrolytic & 4.7 \mu F & 25 V & MS7 \\ C80 & Electrolytic & 1 \mu F & 50 V & MS7 \\ C81 & Ceramic & 0.001 \mu F & 50 V \\ C82 & Electrolytic & 47 \mu F & 25 V & MS9 \\ C83 & Ceramic & 22 \rho F & 50 V \\ C84 & Ceramic & 18 \rho F & 50 V \\ C85 & Trimmer & 20 \rho F & CV05 D 2001 \\ C86 & Ceramic & 27 \rho F & 50 V \\ C87 & Ceramic & 0.001 \mu F & 50 V \\ C88 & Electrolytic & 10 \mu F & 16 V & MS7 \\ C89 & Ceramic & 100 \rho F & 50 V \\ C90 & Electrolytic & 3.3 \mu F & 50 V & MS7 \\ C91 & Electrolytic & 3.3 \mu F & 50 V & MS7 \\ C92 & Ceramic & 0.001 \mu F & 50 V \\ C93 & Barrier Layer & 0.01 \mu F & 50 V \\ C94 & Ceramic & 0.001 \mu F & 50 V \\ C95 & Ceramic & 0.001 \mu F & 50 V \\ C96 & Ceramic & 0.001 \mu F & 50 V \\ C96 & Ceramic & 0.001 \mu F & 50 V \\ C97 & Ceramic & 0.001 \mu F & 50 V \\ C96 & Ceramic & 0.001 \mu F & 50 V \\ C97 & Ceramic & 0.001 \mu F & 50 V \\ C98 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C101 & Ceramic & 0.001 \mu F & 50 V \\ C102 & Ceramic & 0.001 \mu F & 50 V \\ C103 & Ceramic & 470 \rho F & 50 V \\ C104 & Electrolytic & 22 \mu F & 6.3 V & MS7 \\ C105 & Barrier Layer & 0.1 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 16 V \\ C106 & Electrolytic & 0.001 \mu F & 50 V \\ C107 & Ceramic & 0.001 \mu F & 50 V \\ C108 & Ceramic & 0.001 \mu F & 50 V \\ C109 & Ceramic & 470 \rho F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C101 & Ceramic & 0.001 \mu F & 50 V \\ C102 & Ceramic & 470 \rho F & 50 V \\ C103 & Ceramic & 0.001 \mu F & 50 V \\ C104 & Electrolytic & 22 \mu F & 6.3 V & MS7 \\ C106 & Electrolytic & 10 \mu F & 16 V \\ C106 & Ceramic & 0.001 \mu F & 50 V \\ C108 & Ceramic & 0.001 \mu F & 50 V \\ C109 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C100 & Ceramic & 0.001 \mu F & 50 V \\ C1$	
$\begin{array}{rcrcrc} C80 & Electrolytic & 1\mu F & 50V & MS7 \\ C81 & Ceramic & 0.001\mu F & 50V \\ C82 & Electrolytic & 47\mu F & 25V & MS9 \\ C83 & Ceramic & 22pF & 50V \\ C84 & Ceramic & 18pF & 50V \\ C85 & Trimmer & 20pF & CV05D2001 \\ C86 & Ceramic & 27pF & 50V \\ C87 & Ceramic & 0.001\mu F & 50V \\ C88 & Electrolytic & 10\mu F & 16V & MS7 \\ C89 & Ceramic & 100pF & 50V \\ C90 & Electrolytic & 3.3\mu F & 50V & MS7 \\ C91 & Electrolytic & 3.3\mu F & 50V & MS7 \\ C92 & Ceramic & 0.001\mu F & 50V \\ C93 & Barrier Layer & 0.01\mu F & 50V \\ C95 & Ceramic & 0.001\mu F & 50V \\ C96 & Ceramic & 0.001\mu F & 50V \\ C97 & Ceramic & 0.001\mu F & 50V \\ C98 & Ceramic & 0.001\mu F & 50V \\ C99 & Ceramic & 0.001\mu F & 50V \\ C96 & Ceramic & 0.001\mu F & 50V \\ C97 & Ceramic & 0.001\mu F & 50V \\ C98 & Ceramic & 0.001\mu F & 50V \\ C100 & Ceramic & 470pF & 50V \\ C101 & Ceramic & 470pF & 50V \\ C102 & Ceramic & 470pF & 50V \\ C103 & Ceramic & 470pF & 50V \\ C104 & Electrolytic & 22\mu F & 6.3V & MS7 \\ C105 & Barrier Layer & 0.1\mu F & 16V \\ C106 & Electrolytic & 10\mu F & 16V \\ C106 & Electrolytic & 22\mu F & 6.3V & MS7 \\ C106 & Electrolytic & 10\mu F & 16V \\ C106 & Electrolytic & 0.001\mu F & 50V \\ C107 & Ceramic & 0.001\mu F & 50V \\ C108 & Ceramic & 0.001\mu F & 50V \\ C109 & Ceramic & 0.001\mu F & 50V \\ C100 & Ceramic & 470pF & 50V \\ C1010 & Ceramic & 0.001\mu F & 50V \\ C102 & Ceramic & 470pF & 50V \\ C103 & Ceramic & 0.001\mu F & 50V \\ C104 & Electrolytic & 22\mu F & 6.3V & MS7 \\ C105 & Barrier Layer & 0.1\mu F & 16V \\ C106 & Electrolytic & 10\mu F & 16V \\ C107 & Ceramic & 0.001\mu F & 50V \\ C108 & Ceramic & 0.001\mu F & 50V \\ C109 & Ceramic & 0.001\mu F & 50V \\ C100 & Ceramic & 0.001\mu F & 50V \\ C101 & Ceramic & 0.001\mu F & 50V \\ C102 & Ceramic & 0.001\mu F & 50V \\ C103 & Ceramic & 0.001\mu F & 50V \\ C104 & Electrolytic & 10\mu F & 16V \\ C106 & Electrolytic & 0.001\mu F & 50V \\ C108 & Ceramic & 0.001\mu F & 50V \\ C109 & Ceramic & 470pF & 50V \\ C100 & Ceramic & 470pF & 50V \\ C100 & Ceramic & 0.001\mu F & 50V \\ C100 & Ceramic & 470pF & 50V \\$	
C81 Ceramic $0.001 \mu F$ 50V C82 Electrolytic $47 \mu F$ $25 V$ MS9 C83 Ceramic $22 \rho F$ $50V$ C84 Ceramic $18 \rho F$ $50V$ C85 Trimmer $20 \rho F$ $CV05D2001$ C86 Ceramic $27 \rho F$ $50V$ C87 Ceramic $0.001 \mu F$ $50V$ C88 Electrolytic $10 \mu F$ $16V$ MS7 C89 Ceramic $100 \rho F$ $50V$ S7 C90 Electrolytic $3.3 \mu F$ $50V$ MS7 C91 Electrolytic $3.3 \mu F$ $50V$ MS7 C92 Ceramic $0.001 \mu F$ $50V$ C93 Barrier Layer $0.01 \mu F$ $50V$ C94 Ceramic $0.001 \mu F$ $50V$ C93 Barrier Layer $0.001 \mu F$ $50V$ C96 Ceramic $0.001 \mu F$ $50V$ C96 Ceramic $0.001 \mu F$ <	
C82 Electrolytic 47μ F $25V$ MS9 C83 Ceramic 22ρ F $50V$ C84 Ceramic 18ρ F $50V$ C85 Trimmer 20ρ F $CV05D2001$ C86 Ceramic 27ρ F $50V$ C87 Ceramic 0.01μ F $50V$ C88 Electrolytic 10μ F $16V$ MS7 C89 Ceramic 100ρ F $50V$ CS0 C90 Electrolytic 3.3μ F $50V$ MS7 C91 Electrolytic 3.3μ F $50V$ MS7 C92 Ceramic 0.001μ F $50V$ CS0 C93 Barrier Layer 0.01μ F $50V$ CS0 C94 Ceramic 0.001μ F $50V$ CS5 C97 Ceramic 0.001μ F $50V$ CS9 C98 Ceramic 0.001μ F $50V$ C100 Ceramic 470ρ F $50V$ C101 Cera	
C83 Ceramic $22pF$ $50V$ C84 Ceramic $18pF$ $50V$ C85 Trimmer $20pF$ $CV05D2001$ C86 Ceramic $27pF$ $50V$ C87 Ceramic $0.01\muF$ $50V$ C88 Electrolytic $10\muF$ $16V$ MS7 C89 Ceramic $100pF$ $50V$ CS7 C90 Electrolytic $3.3\muF$ $50V$ MS7 C91 Electrolytic $3.3\muF$ $50V$ MS7 C92 Ceramic $0.001\muF$ $50V$ CS6 C93 Barrier Layer $0.01\muF$ $50V$ CS6 C94 Ceramic $0.001\muF$ $50V$ CS6 C95 Ceramic $0.001\muF$ $50V$ CS6 C97 Ceramic $0.001\muF$ $50V$ CS9 C98 Ceramic $0.001\muF$ $50V$ C100 Ceramic $470pF$ $50V$ C100	
C84 Ceramic 18pF 50V C85 Trimmer 20pF CV05D2001 C86 Ceramic 27pF 50V C87 Ceramic 0.001 μ F 50V C88 Electrolytic 10 μ F 16V MS7 C89 Ceramic 100pF 50V CS7 C90 Electrolytic 3.3 μ F 50V MS7 C91 Electrolytic 3.3 μ F 50V MS7 C92 Ceramic 0.001 μ F 50V CS3 Barrier Layer 0.01 μ F 50V CS4 C93 Barrier Layer 0.001 μ F 50V C94 Ceramic 0.001 μ F 50V C95 Ceramic 0.001 μ F 50V C96 Ceramic 0.001 μ F 50V C98 Ceramic 0.001 μ F 50V C100 Ceramic 470pF 50V C101 Ceramic 0.001 μ F 50V	
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$\begin{array}{cccccccccccccccccccccccccccccccccccc$	
$\begin{array}{ccccc} C99 & Ceramic & 470 {\rm pF} & 50 {\rm V} \\ C100 & Ceramic & 0.001 {\rm \mu F} & 50 {\rm V} \\ C101 & Ceramic & 470 {\rm pF} & 50 {\rm V} \\ C102 & Ceramic & 47 {\rm \mu F} & 50 {\rm V} \\ C103 & Ceramic & 0.001 {\rm \mu F} & 50 {\rm V} \\ C104 & Electrolytic & 22 {\rm \mu F} & 6.3 {\rm V} & {\rm MS7} \\ C106 & Barrier Layer & 0.1 {\rm \mu F} & 16 {\rm V} \\ C106 & Electrolytic & 10 {\rm \mu F} & 16 {\rm V} \\ C107 & Ceramic & 0.001 {\rm \mu F} & 50 {\rm V} \\ C108 & Ceramic & 0.001 {\rm \mu F} & 50 {\rm V} \\ C108 & Ceramic & 0.001 {\rm \mu F} & 50 {\rm V} \\ C109 & Ceramic & 470 {\rm pF} & 50 {\rm V} \\ C110 & Ceramic & 0.001 {\rm \mu F} & 50 {\rm V} \\ C111 & Ceramic & 47 {\rm pF} & 50 {\rm V} \\ \end{array}$	
$\begin{array}{ccccccc} C100 & Ceramic & 0.001 \mu F & 50V \\ C101 & Ceramic & 470 p F & 50V \\ C102 & Ceramic & 47 \mu F & 50V \\ C103 & Ceramic & 0.001 \mu F & 50V \\ C104 & Electrolytic & 22 \mu F & 6.3V & MS7 \\ C105 & Barrier Layer & 0.1 \mu F & 16V \\ C106 & Electrolytic & 10 \mu F & 16V & MS7 \\ C107 & Ceramic & 0.001 \mu F & 50V \\ C108 & Ceramic & 0.001 \mu F & 50V \\ C109 & Ceramic & 470 p F & 50V \\ C110 & Ceramic & 0.001 \mu F & 50V \\ C111 & Ceramic & 47 p F & 50V \\ \end{array}$	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	
$\begin{array}{ccccccc} {\rm C102} & {\rm Ceramic} & 47\mu{\rm F} & 50{\rm V} \\ {\rm C103} & {\rm Ceramic} & 0.001\mu{\rm F} & 50{\rm V} \\ {\rm C104} & {\rm Electrolytic} & 22\mu{\rm F} & 6.3{\rm V} & {\rm MS7} \\ {\rm C105} & {\rm Barrier\ Layer} & 0.1\mu{\rm F} & 16{\rm V} \\ {\rm C106} & {\rm Electrolytic} & 10\mu{\rm F} & 16{\rm V} & {\rm MS7} \\ {\rm C107} & {\rm Ceramic} & 0.001\mu{\rm F} & 50{\rm V} \\ {\rm C108} & {\rm Ceramic} & 0.001\mu{\rm F} & 50{\rm V} \\ {\rm C109} & {\rm Ceramic} & 470{\rm pF} & 50{\rm V} \\ {\rm C110} & {\rm Ceramic} & 0.001\mu{\rm F} & 50{\rm V} \\ {\rm C110} & {\rm Ceramic} & 470{\rm pF} & 50{\rm V} \\ {\rm C111} & {\rm Ceramic} & 47{\rm pF} & 50{\rm V} \\ \end{array}$	
$\begin{array}{ccccccc} C104 & Electrolytic & 22 \mu F & 6.3 V & MS7 \\ C105 & Barrier Layer & 0.1 \mu F & 16 V \\ C106 & Electrolytic & 10 \mu F & 16 V & MS7 \\ C107 & Ceramic & 0.001 \mu F & 50 V \\ C108 & Ceramic & 0.001 \mu F & 50 V \\ C109 & Ceramic & 470 p F & 50 V \\ C110 & Ceramic & 0.001 \mu F & 50 V \\ C111 & Ceramic & 47 p F & 50 V \\ \end{array}$	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	
C106 Electrolytic 10μF 16V MS7 C107 Ceramic 0.001μF 50V C108 Ceramic 0.001μF 50V C109 Ceramic 470pF 50V C110 Ceramic 0.001μF 50V C110 Ceramic 0.001μF 50V C111 Ceramic 47pF 50V	
C107 Ceramic 0.001µF 50V C108 Ceramic 0.001µF 50V C109 Ceramic 470pF 50V C110 Ceramic 0.001µF 50V C111 Ceramic 47pF 50V	
C108 Ceramic 0.001μF 50V C109 Ceramic 470pF 50V C110 Ceramic 0.001μF 50V C111 Ceramic 47pF 50V	
C110 Ceramic 0.001µF 50V C111 Ceramic 47pF 50V	
C111 Ceramic 47pF 50V	
(IC-228A: U.S.A., Asia)	
C113 Ceramic 0.001µF 50V	
(IC-228A: U.S.A., Asia)	
C114 Ceramic 39pF 50V (IC-228A: U.S.A., Asia)	
C115 Ceramic 39pF 50V	
(IC-228A: U.S.A., Asia)	
C116 Barrier Layer 0.01µF 25V	
(IC-228A: U.S.A., Asia)	
C117 Electrolytic 0.1µF 50V MS7 (IC-228A: U.S.A., Asia)	
C118 Electrolytic 4.7µF 25V MS7	
C119 Ceramic 120pF 50V	
C120 Barrier Layer 0.0022µF 25V	
C121 Electrolytic 4.7µF 25V MS7	
C122 Ceramic 0.001µF 50V	

[MAIN UNIT]

REF. NO.	DESCRIPTION	PART	ſ NO.
C123	Barrier Layer	0.001µF	25V
C124	Ceramic	470pF	50V 50V BP
C125 C126	Electrolytic Ceramic	1μF 470pF	50V BP 50V
C127	Electrolytic	0.22µF	50V MS7
C128	Ceramic	470pF	50V
C129	Barrier Layer	0.01µF	25V
C130	Ceramic	470pF	50V
C131	Barrier Layer	0.01µF	25V
C132 C133	Ceramic Ceramic	0.001µF 0.001µF	50V 50V
C133	Electrolytic	10µF	16V MS7
C135	Ceramic	22pF	50V
C136	Ceramic	47pF	50V
C137	Ceramic	47pF	50V
C138	Ceramic	47pF	50V 50V (IC-228A/E only)
C139 C140	Ceramic Ceramic	470pF 470pF	50V (IC-228A/E only) 50V (IC-228A/E only)
C141	Ceramic	22pF	50V (IC-228A/E only)
14	Connector		A 1
J1 J2	Connector Connector	TXL-P06P-/ TXL-P13P-/	
JZ J3	Connector	PD09A10N	
J4	Connector	SB13P-HV	
P1	Connector	TMP-P01X	Δ1
P1 P2	Connector	TMP-P01X	
P3	Connector	PI28A10F	,,,,
11/4	O-bl-	000 100	
W1 W2	Cable Cable	OPC-186 OPC-143	
W2 W3	Jumper	JPW-01 R	01
W4	Jumper	JPW-01 R	
W5	Jumper	JPW-01 R	01
W6	Jumper	JPW-01 R	
W7	Jumper	JPW-01 R	
W8 W9	Jumper	JPW-01 R	
W9 W10	Jumper Jumper	JPW-01 R	
W11	Jumper	JPW-01 R	
W 12	Jumper	JPW-01 R	01
W13	Jumper	JPW-01 R	01
W14 W15	Jumper	JPW-02A JPW-02A	
W15 W16	Jumper Shield Cable	(61/99/170/	C31/W13A
W17	(with P1 assembly)	08	A
W18	Shield Cable	61/99/170/	C31/W13A
W19	(with P2 assembly)		A
W20 W21	Wire Wire	23/00/070/	
W21	Wire	23/02/070/	
W23	Wire	23/03/065/	D02/D22
W24	Wire	23/04/065/	
W25	Wire	23/05/065/	
W26	Wire Wire	23/06/060/	
W27 W28	Wire	23/08/060/1	
W29	Jumper		IC-228A/E only)
EP1	Ferrite Bead	DL2-0P2.6	-3-1.2H
EP2	Ferrite Bead	DL2-OP2.6	
EP9	Crystal	Crystal Sea	at 4124
EP10	Crystal	Crystal Sea	
EP11	P.C. Board		MAIN) (IC-228A/E) MAIN) (IC-228H)
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PART NO.

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ELR20

ELR20

50V

25V

MS7

R20 R20

R20 ELR20

ELR20

ELR20

ELR20

R20

RH0421CS3J08A

R20

R20 ELR20

R20

100**Ω**

22kΩ

10kΩ 2.2kΩ

100Ω

3.9kΩ

270Ω

820Ω

3.3kΩ 100kΩ

100kΩ

100kΩ

47Ω 22Ω

82**Ω** 47kΩ

10kΩ 470Ω

470**Ω**

330kΩ 5.6kΩ

100kΩ

100kΩ

15kΩ

180kΩ

47kΩ

4.7kΩ

2.7kΩ

47kΩ

100kΩ

1.5kΩ

1kΩ

100**Ω**

22kΩ 47kΩ

1kΩ

3.3Ω

2.2Ω 1Ω

1Ω

1Ω 10kΩ

1kΩ

10kΩ

1kΩ

100kΩ

470Ω

 $27k\Omega$

27kΩ

5.6kΩ

1.2MΩ

1.2MΩ 100Ω

12kΩ

12kΩ

2.7kΩ

100**Ω**

 $100k\Omega$

10kΩ 100kΩ

4.7kΩ

220**Ω** 4.7kΩ

10kΩ 220kΩ

470kΩ

27kΩ 270Ω

18**Ω** 270**Ω**

10kΩ

0.001µF

4.7µF

REF. NO.	DESCRIPTION	PART NO.	REF. NO.	DESCRIPTIO
IC1	IC	MC3357P	R10	Resistor
C2	IC	μPC1242H	R11	Resistor
C3	IC	AN6541	R12	Resistor
C4	IC	NJM4558D	R13	Resistor
IC5	IC	μPD4094BC	R14	Resistor
		F ·	R15	Resistor
			R16	Resistor
Q1	Transistor	2SC2668 O	R17	Resistor
Q2	FET	2SK241 GR	R18	Resistor
Q2 Q3	1			
	FET	3SK174 L	R19	Resistor
Q4	FET	3SK174 L	R20	Resistor
Q5	Transistor	2SC2458 GR	R21	Resistor
Q6	Transistor	2SC2458 GR	R22	Resistor
Q7	Transistor	2SC2458 GR	R23	Resistor
Q8	Transistor	2SB909M Q/R	R24	Resistor
Q9	Transistor	RN1204	R25	Resistor
Q10	Transistor	2SB909M Q/R	R26	Resistor
Q11	Transistor	RN1204	R27	Resistor
Q12	Transistor	RN2204	R28	Resistor
Q13	Transistor	2SC2458 GR	R29	Resistor
Q14	Transistor	RN1204	R30	Resistor
Q15	FET	2SJ105 GR	R31	Resistor
Q16	Transistor	RN1204	R32	Resistor
Q10 Q17	Transistor	RN1204	R33	Resistor
	Transistor			
Q18	ransistor	RN2204	R34	Resistor
			R35	Resistor
.	_		R36	Trimmer
D1	Zener	RD6.2E B2	R37	Resistor
D2	Diode	1\$953	R38	Resistor
D3	Diode	18953	R39	Resistor
D4	Varicap	1SV50E	R40	Resistor
D5	Varicap	1SV50E	R41	Resistor
D6	Varicap	1SV50E	R42	Resistor
D7	Varicap	1SV50E	R43	Resistor
D8	Diode	1S953	R44	Resistor
D9	Diode	1S953	R45	Resistor
D10	Zener	RD6.2E B2	R46	Resistor
D11	Diode	1\$953	R47	Resistor
D12	Diode	1\$953	R48	Resistor
D13	Diode	1SS53	R49	Resistor
D13	Diode	18853	R50	Resistor
D14 D15	Diode	1SS53	R51	Resistor
		18853		
D16	Diode		R52	Resistor
D17	Zener	RD5.1E B2	R53	Resistor
D18	Diode	1SS53	R54	Resistor
D19	Diode	1 SS 53	R55	Resistor
			R56	Resistor
	_		R57	Resistor
FI1	Ceramic	CFW455E	R58	Resistor
FI2	Crystal	17M15B	R59	Resistor
			R60	Resistor
			R61	Resistor
X1	Discriminator	CDB455C7A	R62	Resistor
X2	Crystal	CR-166	R63	Resistor
			R64	Resistor
			R65	Resistor
L1	Coil	LS-331	R66	Resistor
L2	Coil	LS-331	R67	Resistor
L3	Coil	LS-331	R68	Resistor
L4	Coil	0.22µH LAL02KR R22M	R69	Resistor
L5	Coil	LS-291	R70	Resistor
L6	Coil	LS-291	R71	Resistor
L0 L7	Coil	LS-291	R72	Resistor
L7 L8	Coil	LS-291	R73	
-0	001	L0-231		Resistor
			R74	Resistor
	D · · ·		R75	Resistor
R1	Resistor	1.5kΩ ELR20	R76	Resistor
R2	Resistor	1.5kΩ ELR20	R77	Resistor
R3	Resistor	47kΩ ELR20	R78	Resistor
R4	Resistor	100 Ω ELR20	R79	Resistor
R5	Resistor	1.5k Ω ELR20	R80	Resistor
R6	Resistor	1k Ω ELR20		
R7	Resistor	56kΩ ELR20		
R8	Resistor	18kΩ ELR20	C1	Ceramic
	Resistor	100 Ω R20	C2	Electrolytic
R9				

[RX UNIT]

REF. NO.	DESCRIPTION	PAR	t no.	
C3	Tantalum	0.1µF	35V	DN
C4	Ceramic	82pF	50V	
C5 C6	Barrier Layer Electrolytic	0.1μF 4.7μF	16V 25V	MS7
C0 C7	Electrolytic	4.7μF 0.1μF	20V	MS7
C8	Ceramic	120pF	50V	inor
C9	Ceramic	5pF	50V	
C10	Ceramic	47pF	50V	
C11	Ceramic	120pF	50V	
C12 C13	Ceramic Barrier Layer	47pF 0.01µF	50V 25V	
C14	Ceramic	68pF	50V	
C15	Ceramic	3pF	50V	
C16	Ceramic	68pF	50V	
C17	Ceramic	0.001µF	50V	
C18 C19	Ceramic Barrier Layer	0.001μF 0.01μF	50V 25V	
C20	Ceramic	0.001µF	50V	
C21	Ceramic	0.5pF	50V	
C22	Ceramic	7pF	50V	
C23	Ceramic	2pF	50V	
C24 C25	Ceramic Ceramic	0.35pF 10pF	50V 50V	
C26	Ceramic	0.5pF	50V	
C27	Ceramic	1pF	50V	
C28	Ceramic	10pF	50V	
C29	Ceramic	0.5pF	50V	
C30	Ceramic	1pF	50V	
C31 C32	Ceramic Ceramic	10pF	50V 50V	
C32 C33	Ceramic	0.001µF 0.001µF	50V	
C34	Ceramic	0.001µF	50V	
C35	Ceramic	0.001µF	50V	
C36	Ceramic	68pF	50V	
C37	Ceramic	0.5pF	50V	
C38 C39	Ceramic Ceramic	22pF 6pF	50V 50V	
C40	Ceramic	0.001µF	50V	
C41	Ceramic	470pF	50V	
C42	Ceramic	0.001µF	50V	
C43	Ceramic	0.001µF	50V	
C44 C45	Ceramic Ceramic	0.001µF 470pF	50V 50V	
C46	Ceramic	0.001µF	50V	
C47	Ceramic	0.001µF	50V	
C48	Ceramic	47pF	50V	
C49	Barrier Layer	0.0015µF	25V	
C50 C51	Ceramic Barrier Layer	33pF 0.0015µF	50V 25V	
C52	Barrier Layer	0.01µF	25V	
C53	Ceramic	0.001µF	50V	
C54	Tantalum	1µF	35V	DN
C55	Ceramic Parrier Lavor	0.001µF	50V	
C56 C57	Barrier Layer Barrier Layer	0.01μF 0.01μF	25V 25V	
C58	Barrier Layer	0.01μF	25V 25V	
C59	Ceramic	0.001µF	50V	
C60	Electrolytic	1μF	50V	MS7
C61	Barrier Layer	0.01µF	25V	MOR
C62 C63	Electrolytic Ceramic	10μF 470pF	10V 50V	MS5
C63 C64	Tantalum	470pF 0.1μF	35V	DN
C65	Electrolytic	47µF	16V	SS
C66	Electrolytic	220µF	16V	SS
C67	Electrolytic	47μF	16V	SS
C68 C69	Electrolytic Barrier Layer	220µF 0.1µF	16V 16V	SS
C70	Electrolytic	0.1μF 470μF	16V	SS
C71	Tantalum	1μF	35V	DN
C72	Tantalum	4.7μF	16V	DN
C73	Ceramic	0.001µF	50V	
C74 C75	Barrier Layer Barrier Layer	0.01μF 0.01μF	25V 25V	
C75 C76	Barrier Layer	0.01µF	25V 25V	
C77	Barrier Layer	0.01µF	25V	

[RX UNIT]

•

REF. NO.	DESCRIPTION	PART	'NO.
C78	Barrier Layer	0.01µF	25V
C79	Barrier Layer	0.0047µF	25V
C80	Mylar	0.056µH 0.001µF	563K 50V F2D 50V
C81 C82	Ceramic Electrolytic	10µF	16V MS7
C83	Electrolytic	4.7μF	25V MS5
C84	Electrolytic	4.7μF	25V MS7
C85	Electrolytic	1μF	50V MS7
C86	Electrolytic	1μF	50V MS7
C87 C88	Ceramic Ceramic	0.001µF 0.001µF	50V 50V
C89	Ceramic	47pF	50V
C90	Ceramic	47pF	50V
C91	Ceramic	0.001µF	50V
C92	Ceramic	47pF	50V
C93 C94	Ceramic Ceramic	0.001µF 0.001µF	50V 50V
C94 C95	Ceramic	0.001µF	50V 50V
C96	Ceramic	0.001µF	50V
C97	Ceramic	0.001µF	50V
C98	Ceramic	0.001µF	50V
C99	Ceramic	0.001µF	50V
C100 C101	Ceramic Ceramic	0.001µF 0.001µF	50V 50V
C102	Ceramic	0.001µF	50V
C103	Electrolytic	3.3µF	50V MS7
C104	Ceramic	0.001µF	50V
C105	Ceramic	0.001µF	50V
C106	Ceramic	0.001µF	50V
C107	Ceramic	0.001µF	50V
J1	Connector	TMP-J01X-/	42
J2	Connector	TMP-J01X-/	42
J3	Connector	B3B-EH-S	
J4 J5	Connector Connector	HSJ0836-0 5124-13BH	
J5 J6	Connector	86B-EH-S	
	0000.01	000 1.1.0	
EP1	P.C. Board	B-1688B (F	RX)
1			

SECTION 9 OPTIONAL UNITS

9-1 UT-40 TONE SQUELCH UNIT CIRCUIT DESCRIPTION

9-1-1 GENERAL DESCRIPTION

IC1 is a tone encoder/decoder IC chip that outputs and detects 37 different kinds of tones. A tone is set by serial data from IC1 on the EF UNIT in the IC-228A/E/H transceiver.

IC2 functions as a serial/parallel converter, applying 6-bit parallel data to IC1. The following table shows the relation between frequency and input data in IC1.

OUTPUT					10	C1 INI	PUT P	IN NU	JMBE	R		IC1 INPUT PIN NUMBER								
[Hz]	3	4	5	6	7	8	FREQUENCY [Hz]	3	4	5	6	7	8	[Hz]	3	4	5	6	7	8
67.0	н	L	н	н	н	L	110.9	н	L	н	L	н	н	173.8	L	L	L	н	L	н
71.9	L	L	н	н	н	L	114.8	L	L	н	L	н	н	179.9	Н	н	н	L	L	н
74.4	н	н	L	н	н	L	118.8	н	н	L	L	н	н	186.2	L	н	Н	L	L	Η
77.0	L	н	L	н	н	L	123.0	L	н	L	L	н	н	192.8	Н	L	Η	L	L	н
79.7	н	L	L	н	Н	L	127.3	Н	L	L	L	н	н	203.5	L	L	H	L	L	н
82.5	L	L	L	н	н	L	131.8	L	L	L	L	н	н	210.7	н	Н	L	L	L	н
85.4	н	н	н	L	Н	L	136.5	Н	н	н	н	L	н	218.1	L	н	L	L	L	н
88.5	L	н	н	L	Н	L	141.3	L	н	н	н	L	н	225.7	Н	L	L	L	L	Н
91.5	н	L	н	L	Н	L	146.2	Н	L	н	н	L	н	233.6	L	L	L	L	Ľ	н
94.8	н	L	L	н	н	Н	151.4	L	L	н	Н	L	н	241.8	Н	Н	Н	Н	Н	L
100.0	L	L	L	н	Н	Н	156.7	Н	н	L	н	L	н	250.3	L	Η	Н	Н	Н	L
103.5	Н	Н	н	L	Н	н	162.2	L	Н	L	Н	L	Н		_	_	1	—	ł	—
107.2	L	Н	н	L	Н	Н	167.9	Н	L	L	Н	L	Н		_	-	-	_	-	—

H: HIGH L: LOW

9-1-2 ENCODER CIRCUIT

Pin 26 in IC1 outputs a programmed tone frequency when pin 12 in IC1 becomes "L."

Q4 functions as a buffer amplifier. The collector of Q4 outputs the tone signal and the signal is applied to the VCO circuit to be modulated.

Tone deviation can be adjusted by R10.

9-1-3 DECODER CIRCUIT

Detected signals from pin 9 in IC1 on the RX UNIT of the IC-228A/E/H are applied to pin 29 in IC1 on the UT-40 through the DET line. When the signals have a tone modulated and the tone is matched with the programmed tone frequency by IC2, pin 23 in IC1 changes from "HIGH" to "LOW."

• When the tone squelch function is turned OFF:

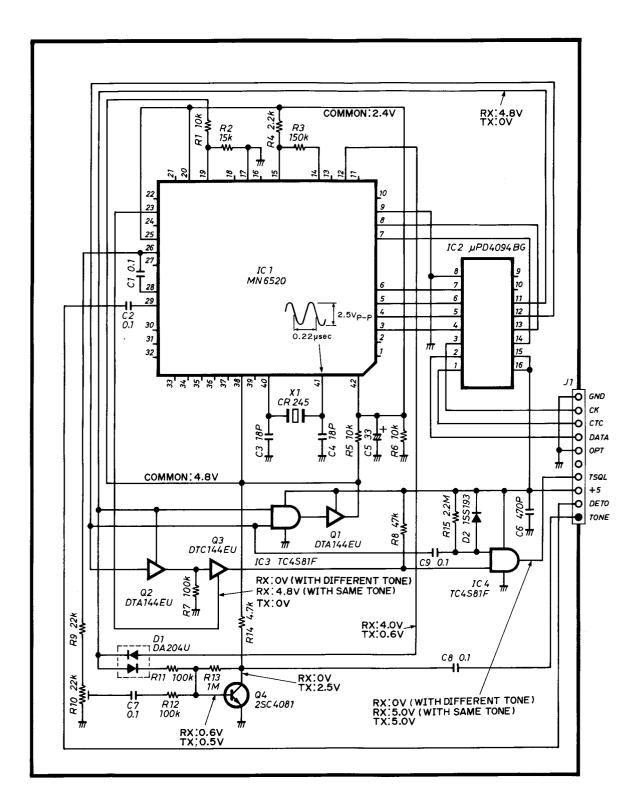
Both pins 11 and 12 in IC2 are "HIGH" and +5V are not applied to IC1. Q2 and Q3 turn OFF and the TSQL line is "HIGH."

• When the tone squelch function is turned ON:

Pin 11 of IC2 is "HIGH" and pin 12 of IC2 is "LOW." Both Q2 and Q3 turn ON.

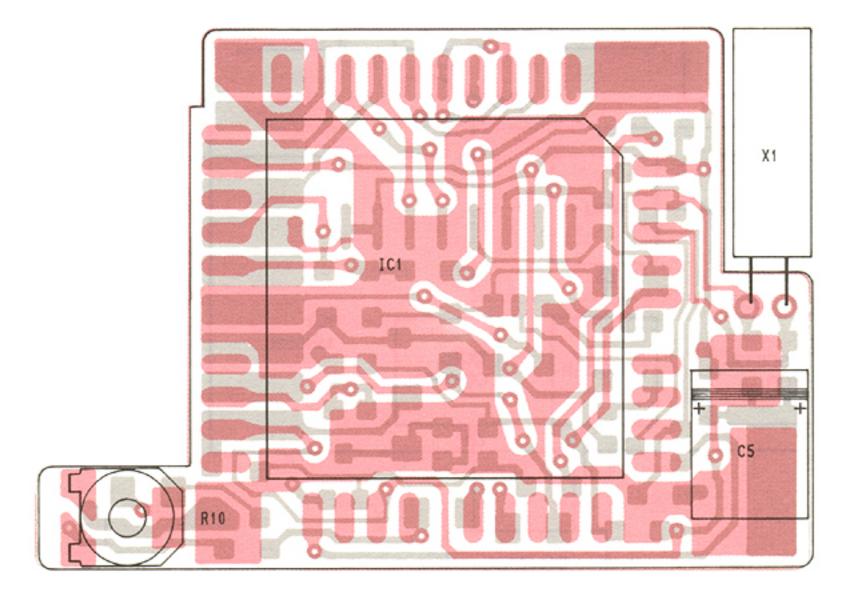
When the received tone frequency is not matched with the programmed tone frequency, pin 23 of IC1 is "LOW" and the TSQL line is "LOW."

When the received tone frequency is matched with the programmed tone, pin 23 becomes "HIGH" and the TSQL line becomes "HIGH."

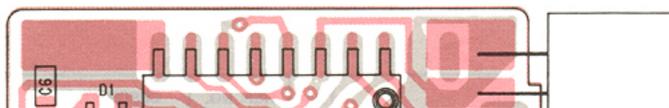


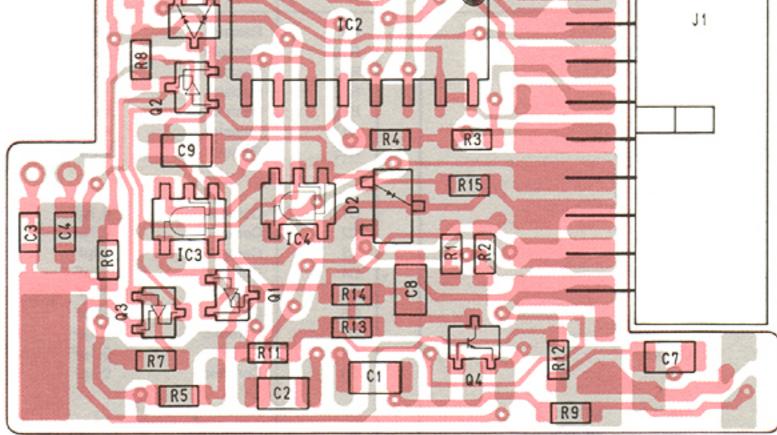
9-3 UT-40 BOARD LAYOUTS

COMPONENT SIDE



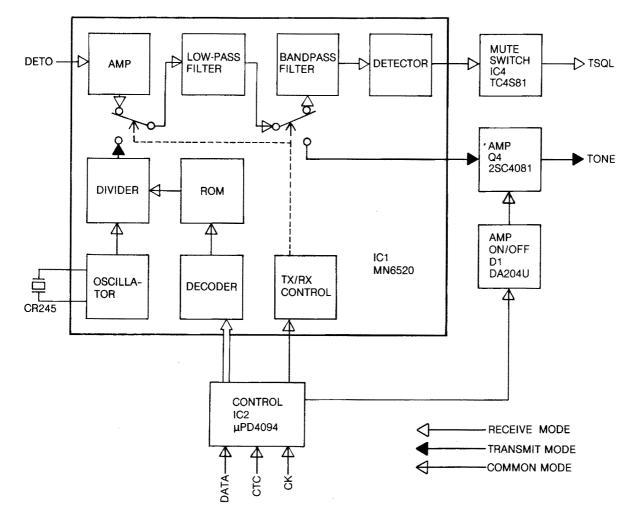
FOIL SIDE





9 — 3

9-4 UT-40 BLOCK DIAGRAM



.

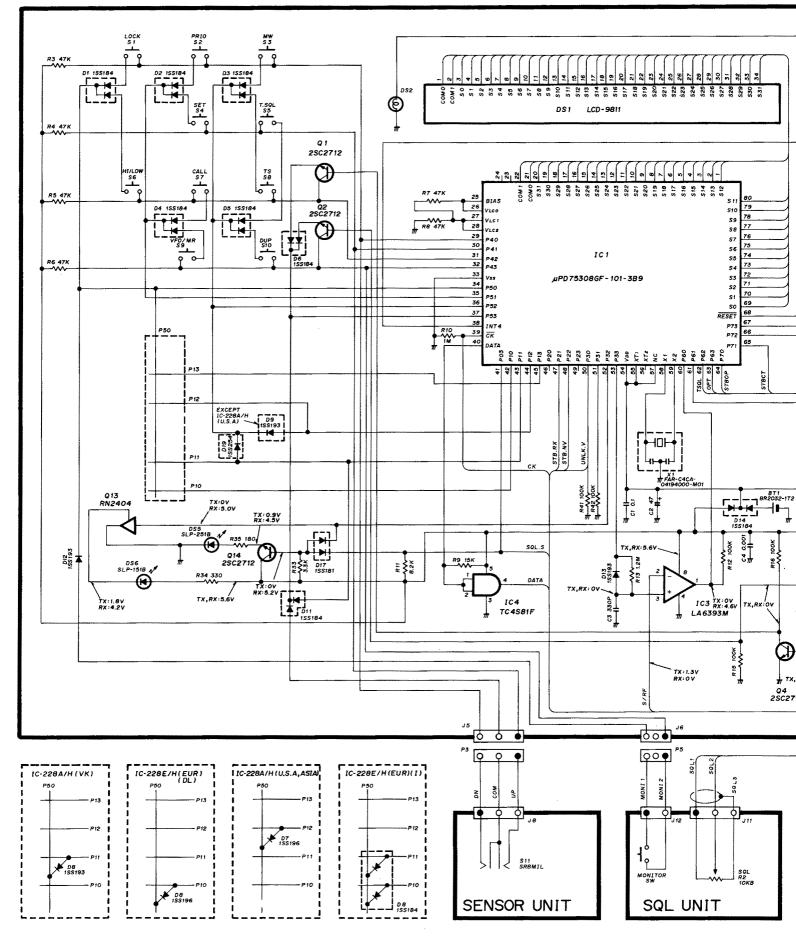
9-5 UT-40 PARTS LIST

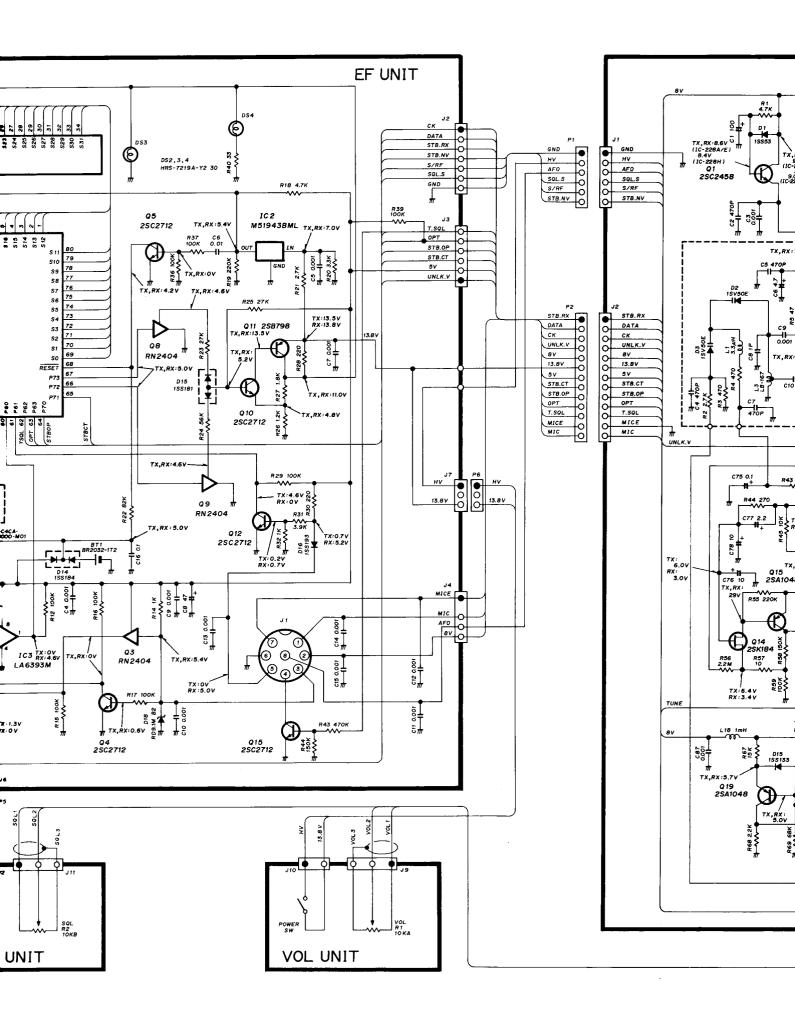
[T. SQL UNIT]

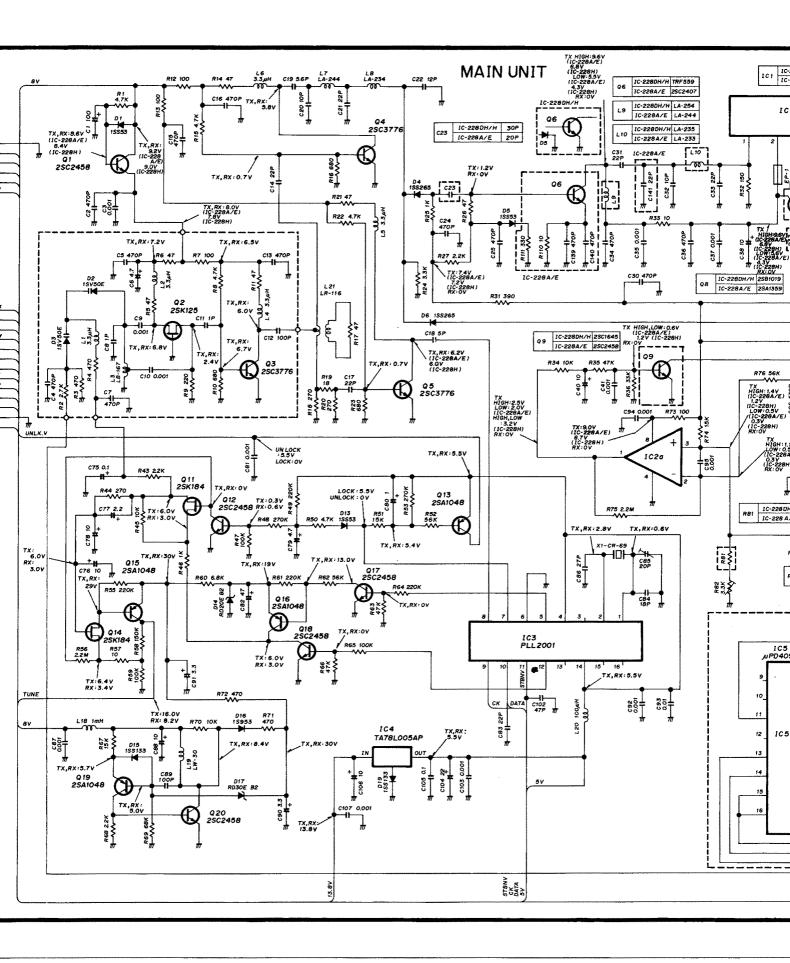
REF. NO.	DESCRIPTION	PART NO.	REF. NO.	DESCRIPTION	PART NO.	
IC1	IC	MN6520	R9	Resistor	22kΩ	MCR03 EZH J
IC2		µPD4094BG	R10	Trimmer	22kΩ	RH04A3AJ4J
IC3	IC	TC4S81F	R11	Resistor	100kΩ	MCR03 EZH J
IC4	l ic	TC4S81F	R12	Resistor	100kΩ	MCR03 EZH J
			R13	Resistor	1MΩ	MCR03 EZH J
			R14	Resistor	4.7kΩ	MCR03 EZH J
Q1	Transistor	DTA144EU	R15	Resistor	2.2MΩ	MCR03 EZH J
Q2	Transistor	DTA144EU				
Q3	Transistor	DTC144EU				
Q4	Transistor	2SC4081 R	C1	Ceramic	0.1µF	GRM40 F
			C2	Ceramic	0.1µF	GRM40 F
			C3	Ceramic	50µF	GRM39 SL 180.
D1	Diode	DA204U	C4	Ceramic	50µF	GRM39 SL 180.
D2	Diode	1SS193	C5	Tantalum	33µF	TESVC0G336M1
			C6	Ceramic	50µF	GRM39 B 471K
			C7	Ceramic	0.1µF	GRM40 F
X1	Crystal	CR245	C8	Ceramic	0.1µF	GRM40 F
			C9	Ceramic	0.1µF	GRM40 F
R1	Resistor	10kΩ MCR03 EZH J				
R2	Resistor	15kΩ MCR03 EZH J	J1	Connector	PI28A10M	
R3	Resistor	150kΩ MCR03 EZH J				
R4	Resistor	2.2kΩ MCR03 EZH J				
R5	Resistor	10kΩ MCR03 EZH J	EP1	P.C. Board	B-1577C	
R6	Resistor	10kΩ MCR03 EZH J				
R7	Resistor	100kΩ MCR03 EZH J				
R8	Resistor	47kΩ MCR03 EZH J				

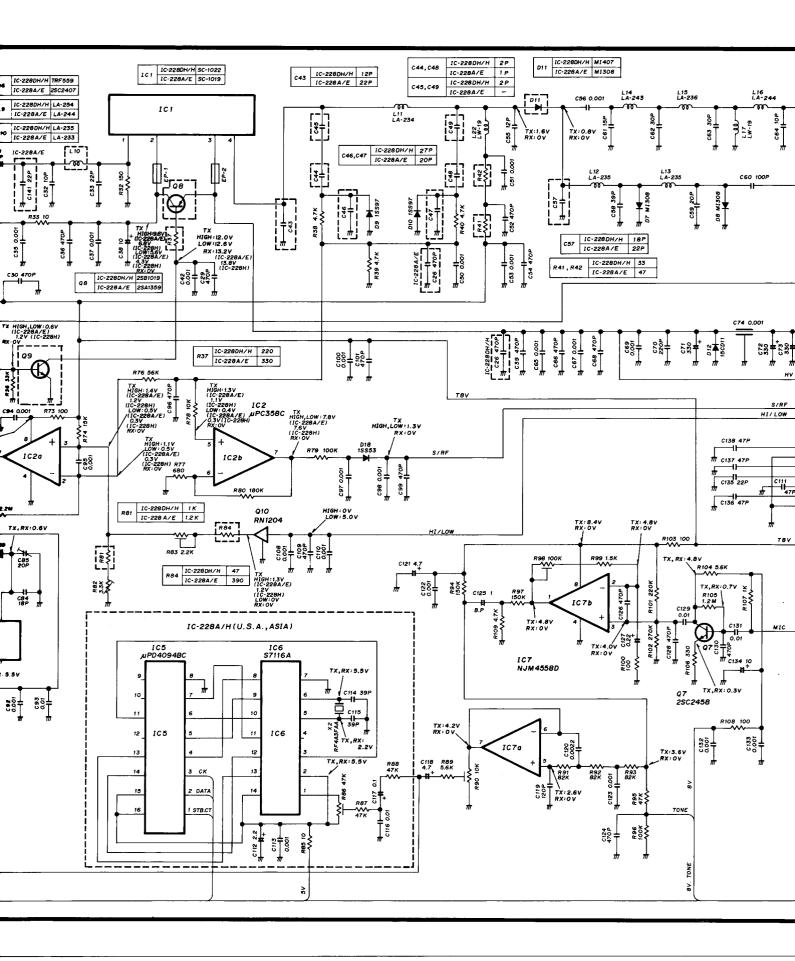
SECTION 10 VOLTAGE DIAGRAM

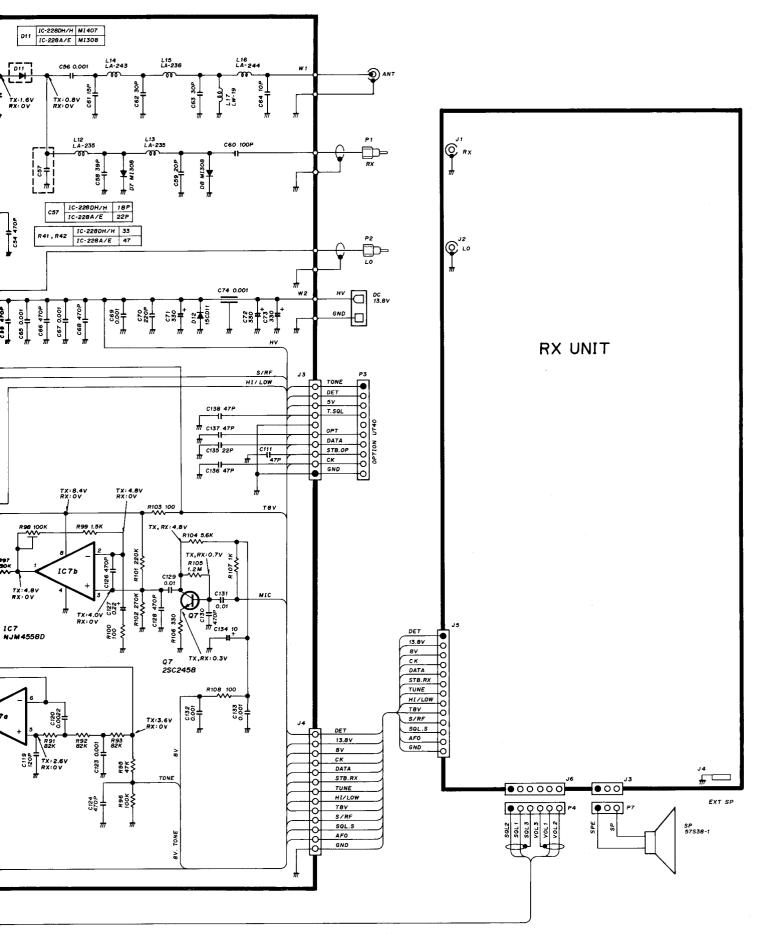
• EF AND MAIN UNITS

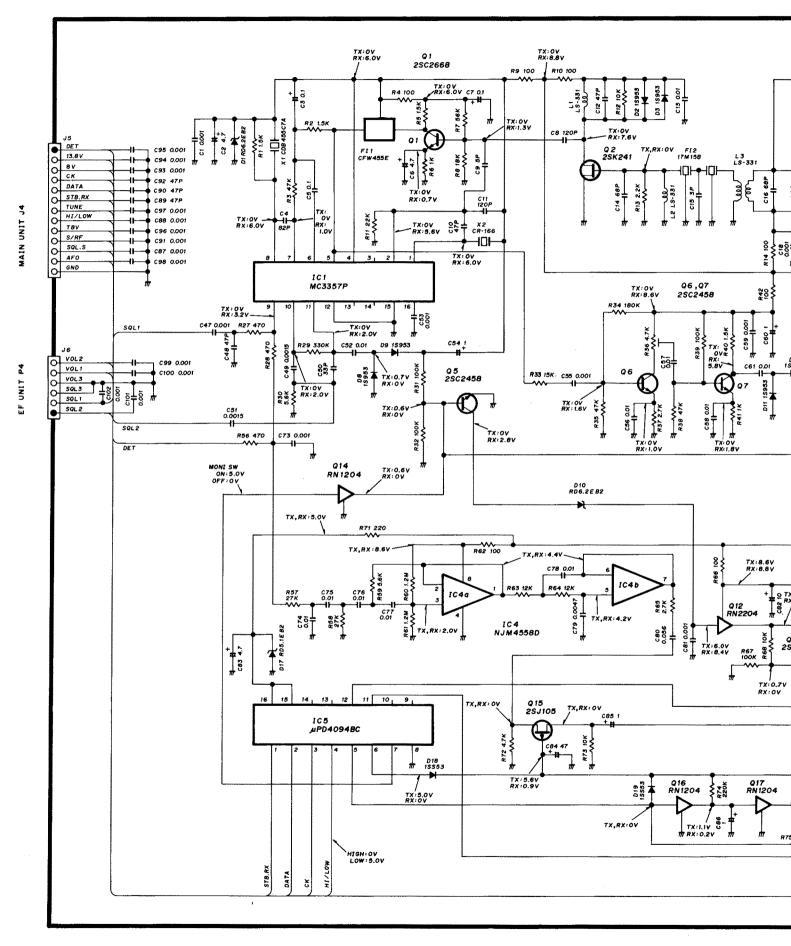


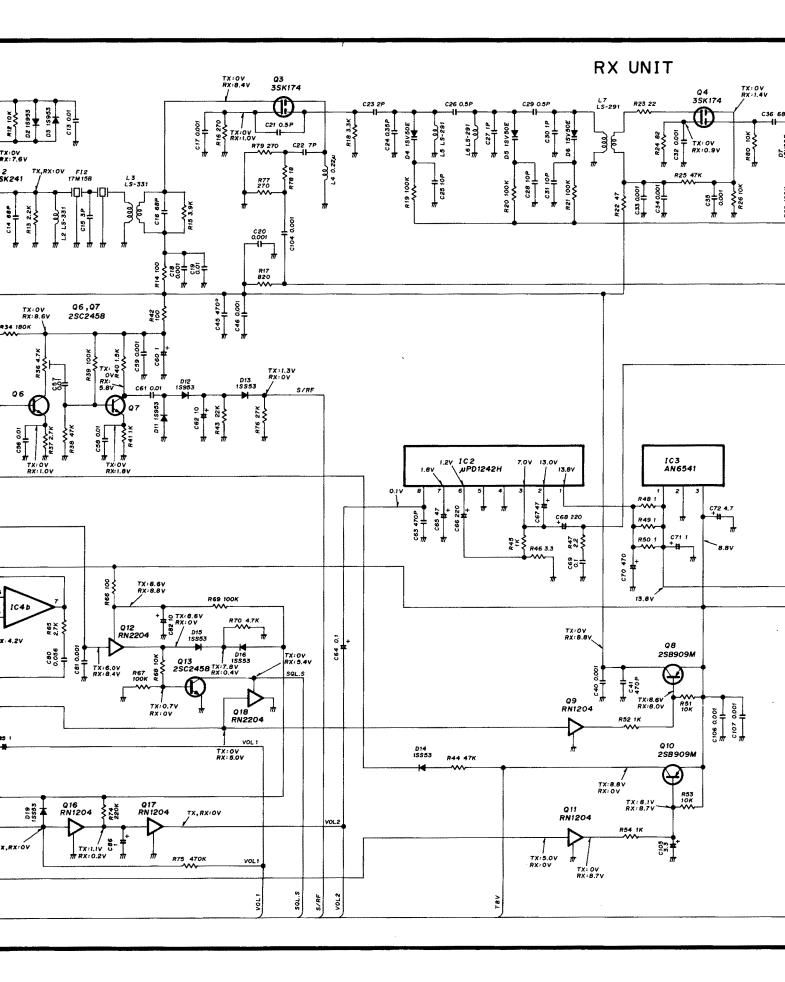


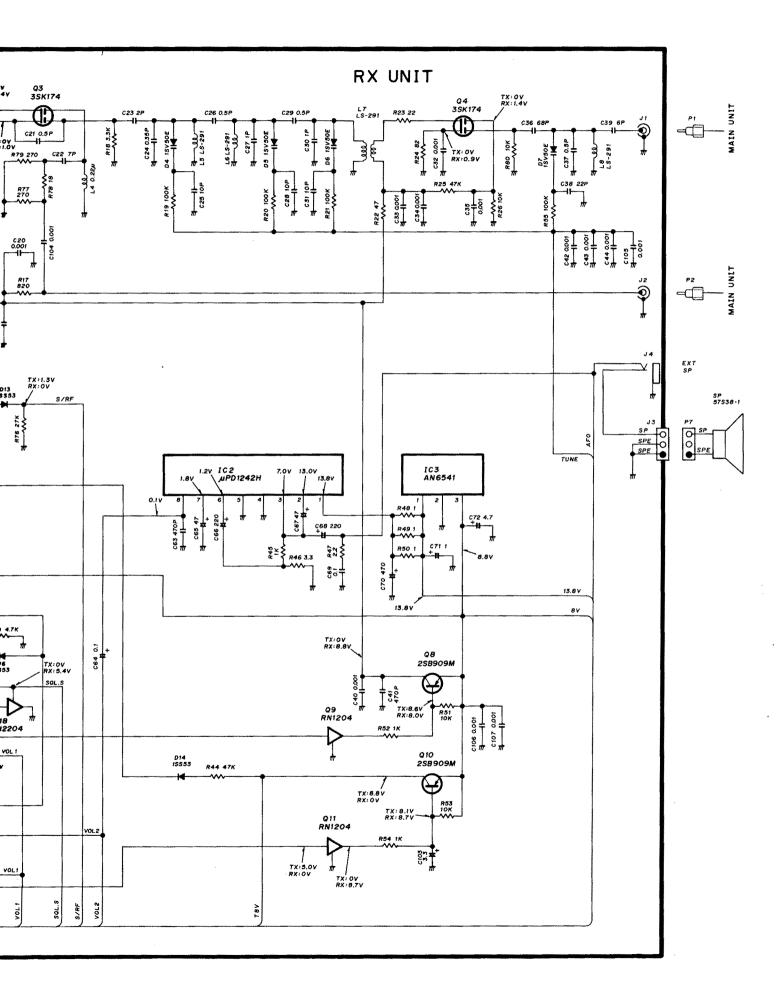












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